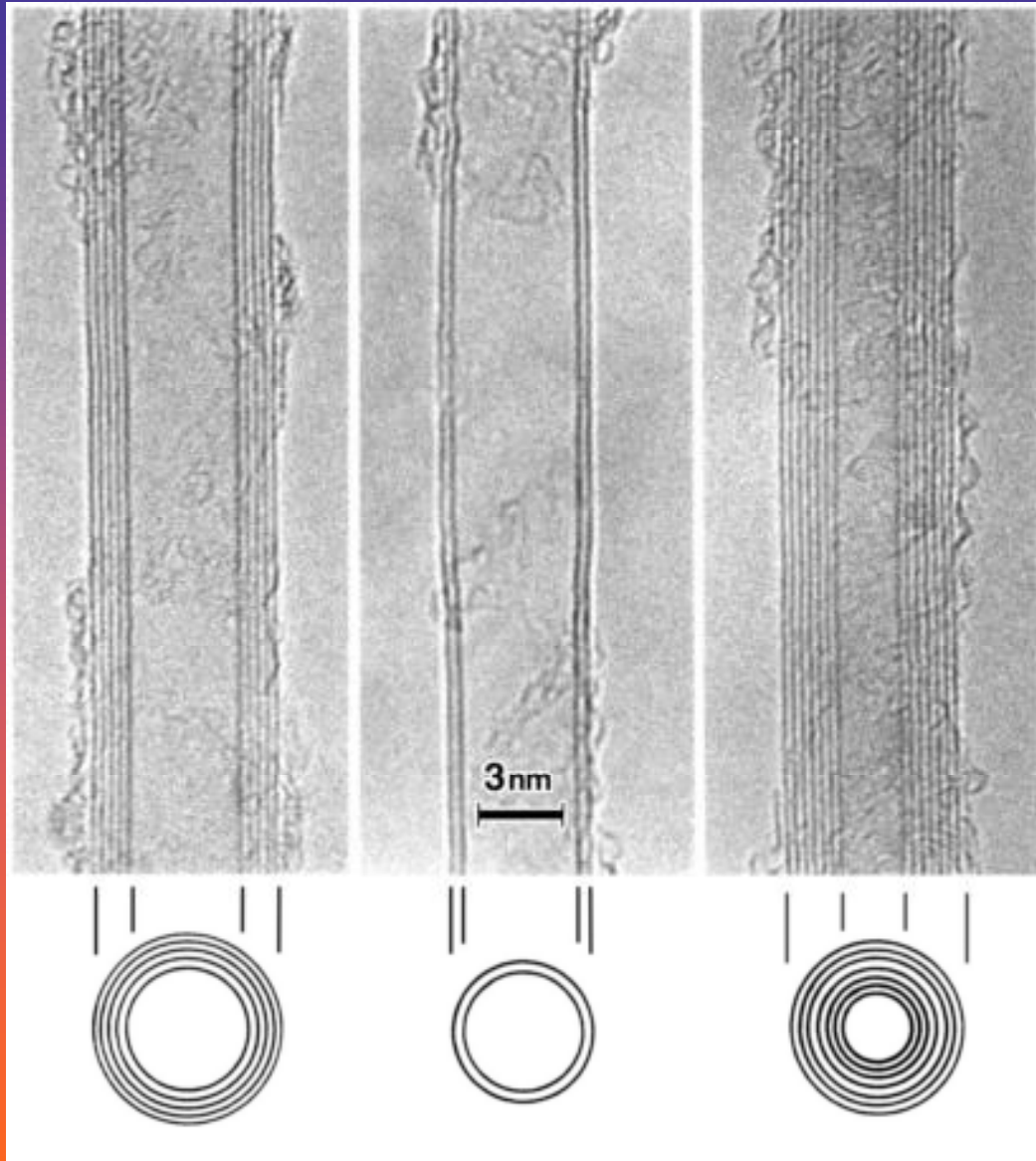
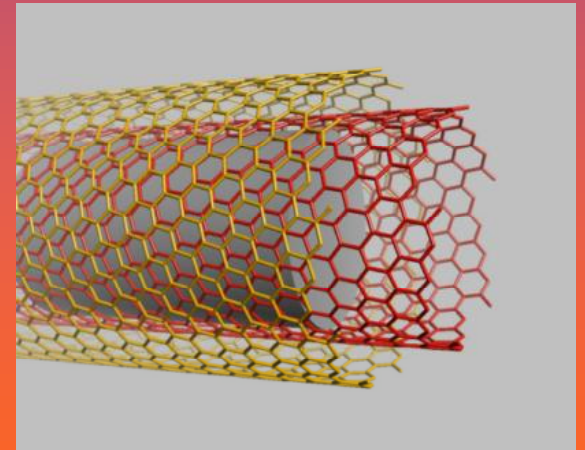


Dawn of Carbon Nanotechnology in 1991



Iijima (NEC) found these Carbon nanotubes in soot formed by arc discharge of carbon containing Fe.



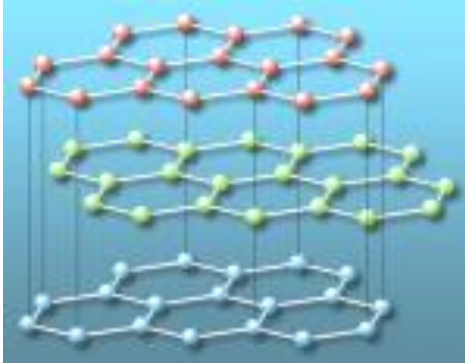
Handa (NEC)

Potential application of CNTs

- Electronic Devices
- Large area FET
- Transparent electrically conducting films
- Coating
- Mechanical engineering fields
- Medical fields

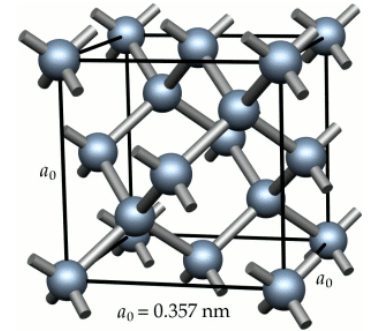
(Robot)

Carbonaceous materials



Lanzara Research Group

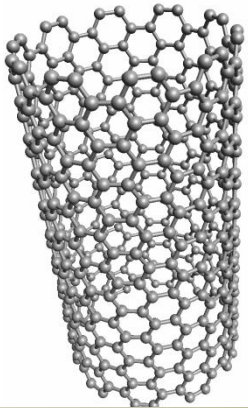
Diamond
Graphite



John Baez's Stuff

Carbon nanotube

(Single-walled, Multi-walled, Nanohorn)

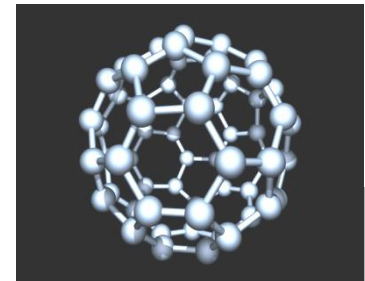


Fullerene

Others

Amorphous carbon

ICSD for WWW



T. Kawauchi, TUT



Yanagi et al. Diamond Related Mater. 2008

How to make?

- Structure (C-C bonds)
- Shape
- Size
- Quality
- Quantity

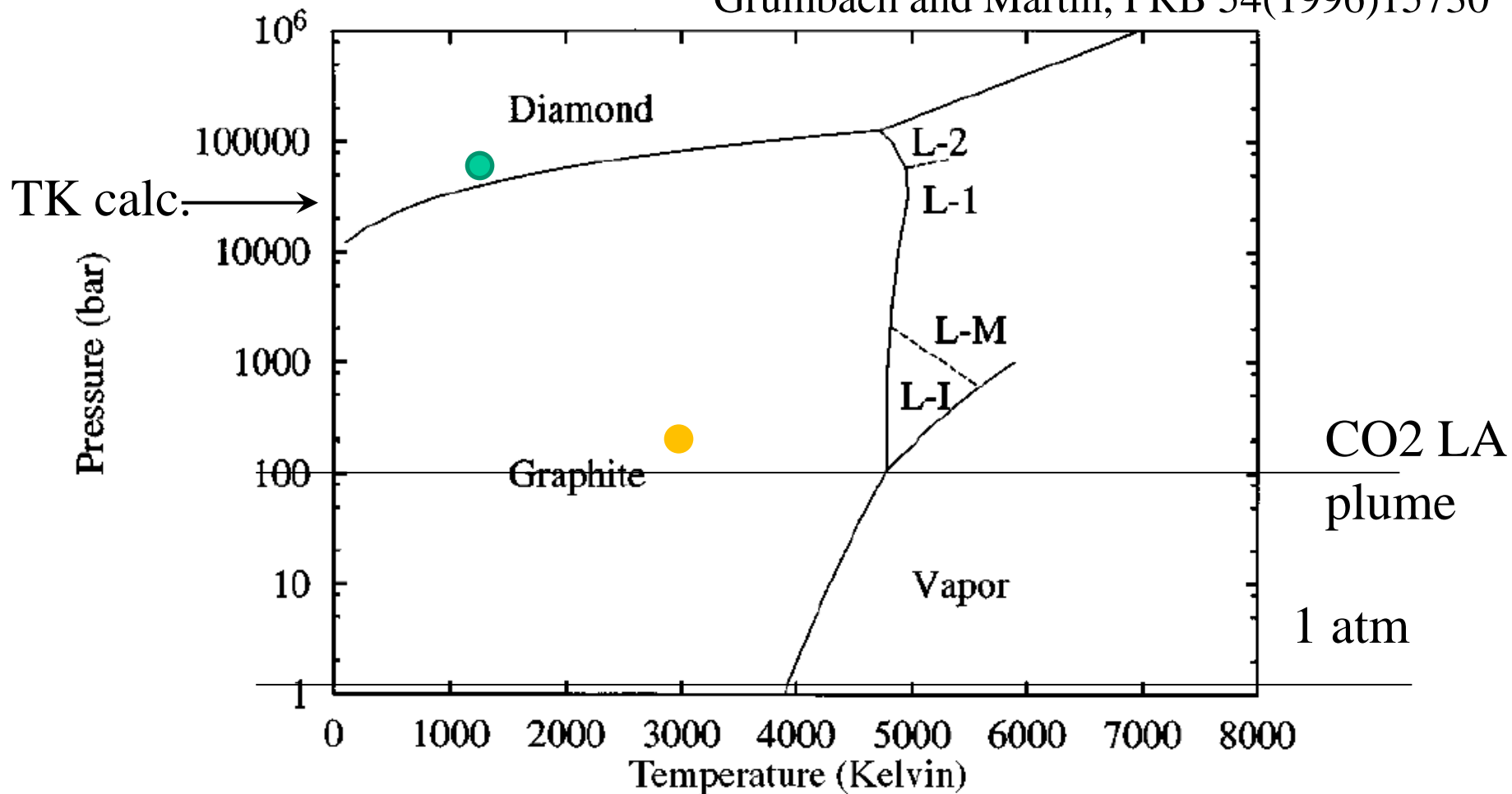
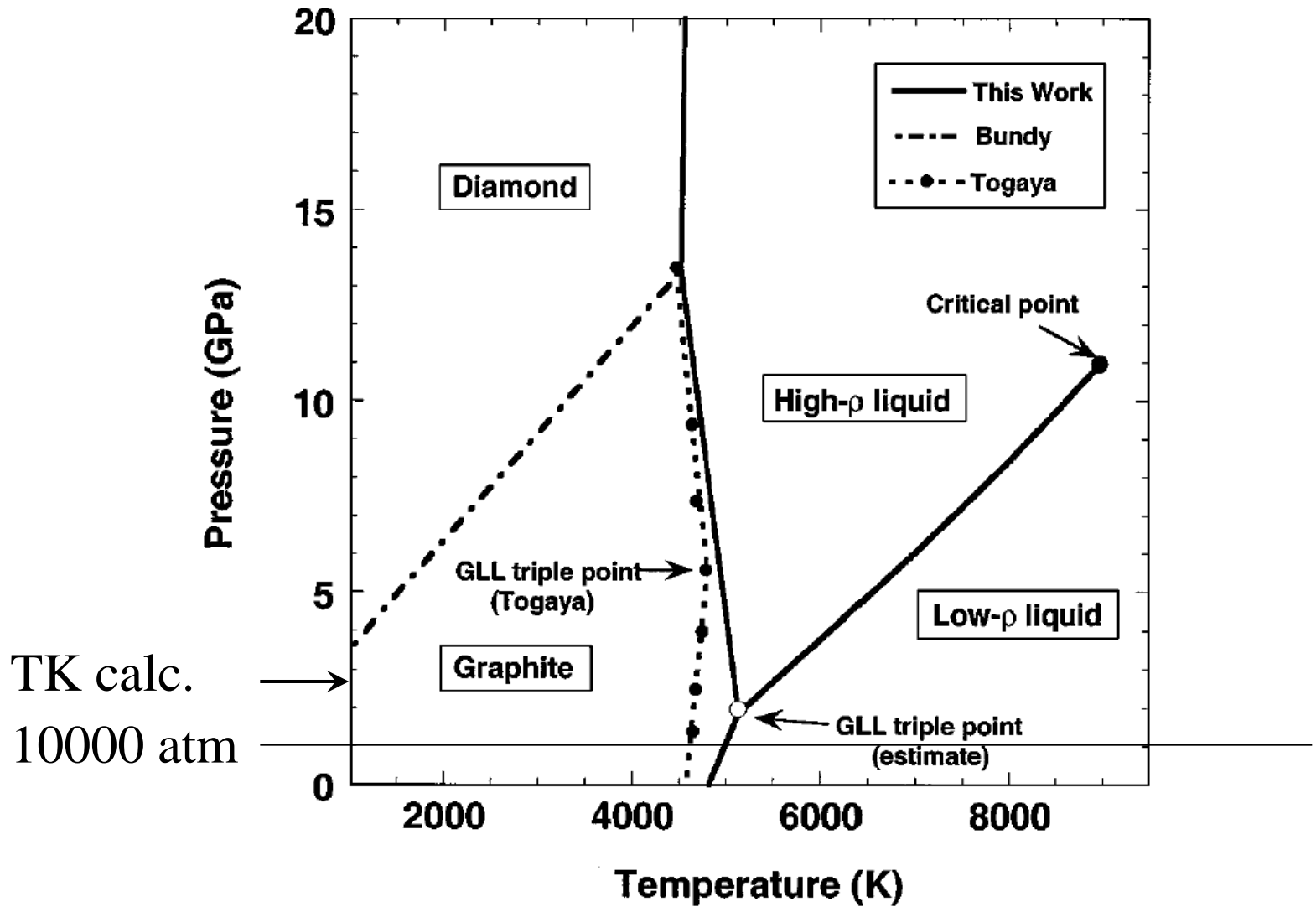
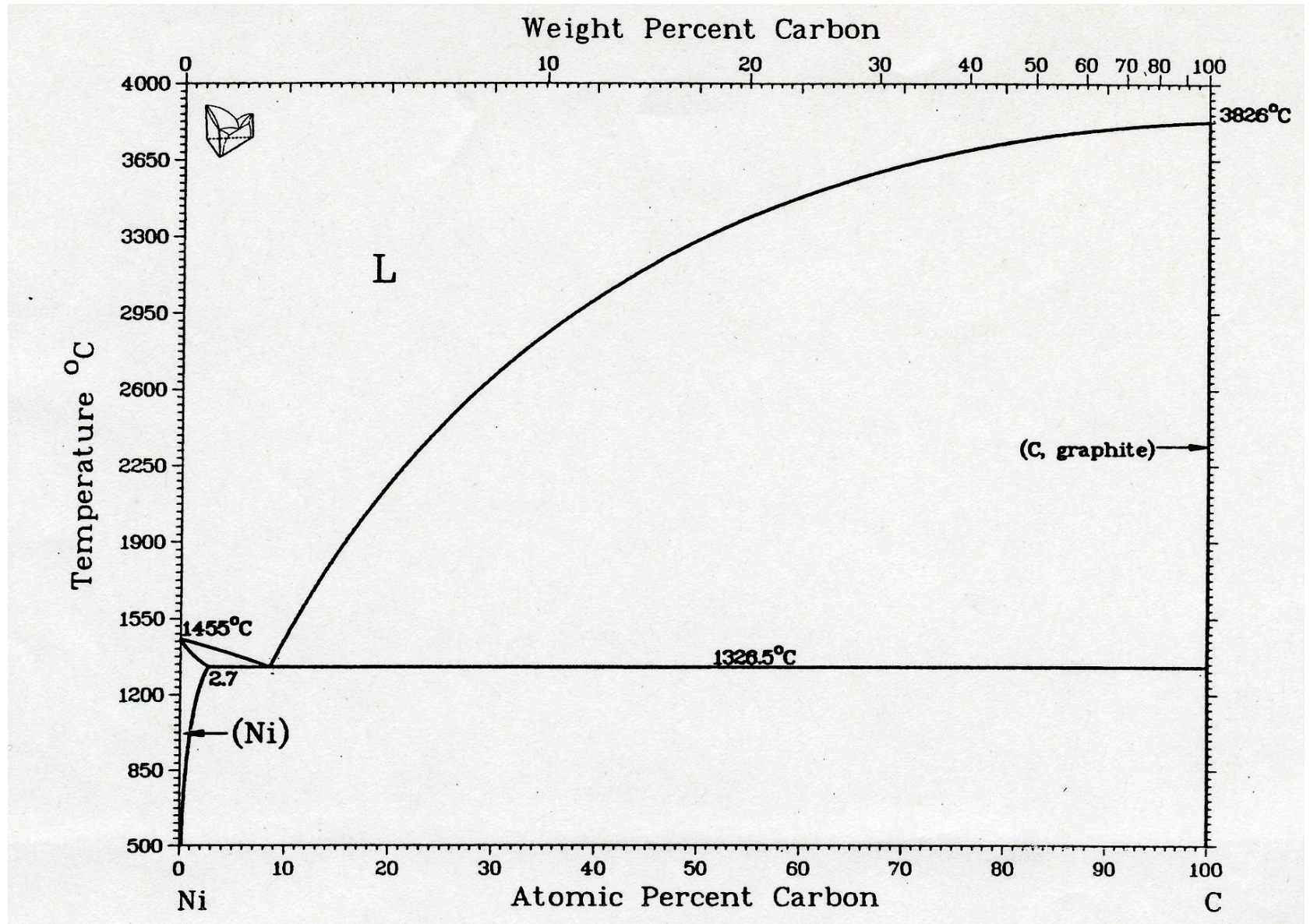


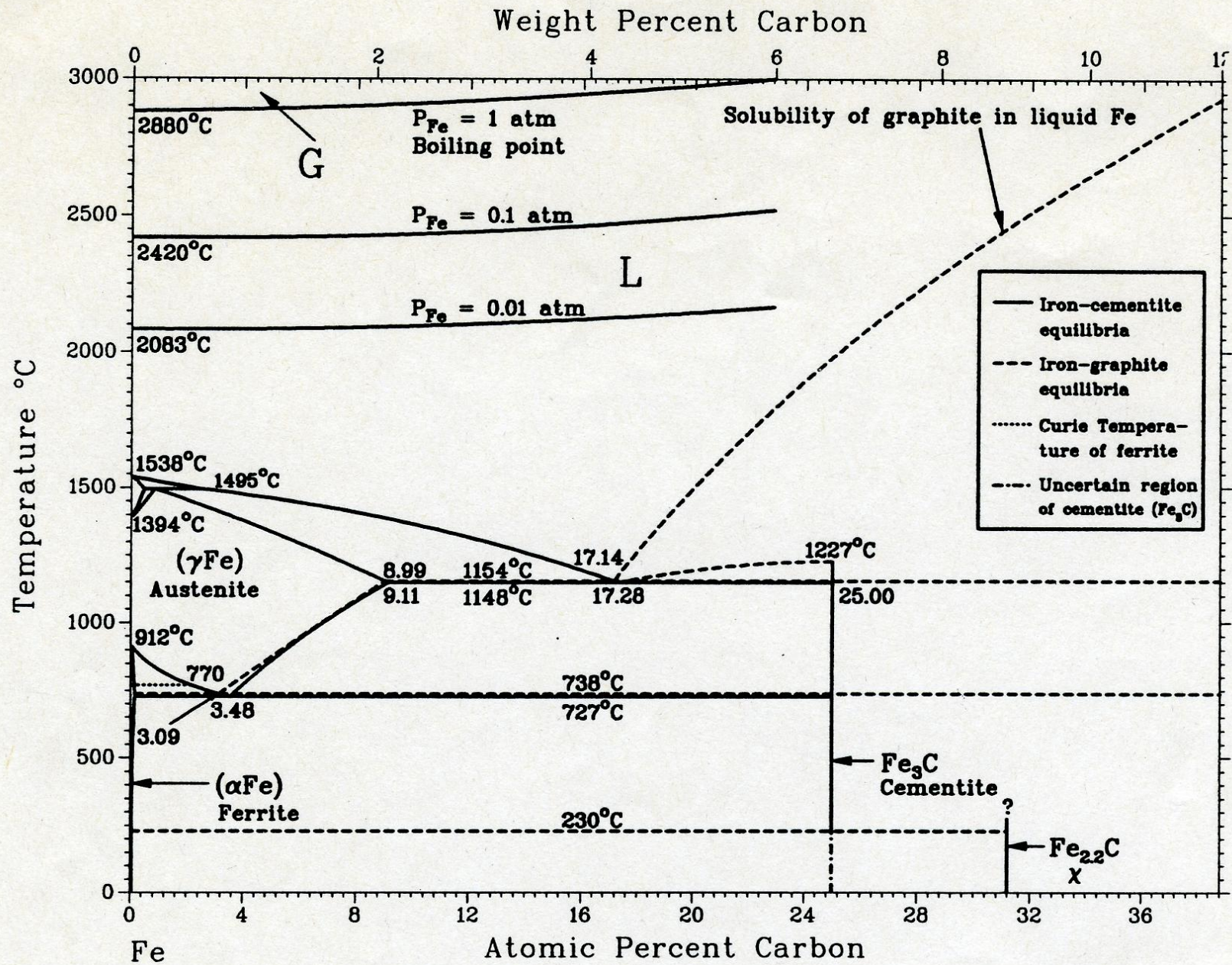
FIG. 1. Phase diagram of carbon at low pressures. Solid lines indicate phase boundaries for which some experimental evidence exists (Ref. 14). Dashed lines indicate theoretically proposed phase boundaries: liquid insulator (*L-I*) to liquid metal (*L-M*) (Ref. 15) and graphitelike liquid (*L-1*) to diamondlike liquid (*L-2*) (Ref. 16).



Glosli and Ree, *PRL* 82(1999)4659.

Metal-Carbon Phase Diagram

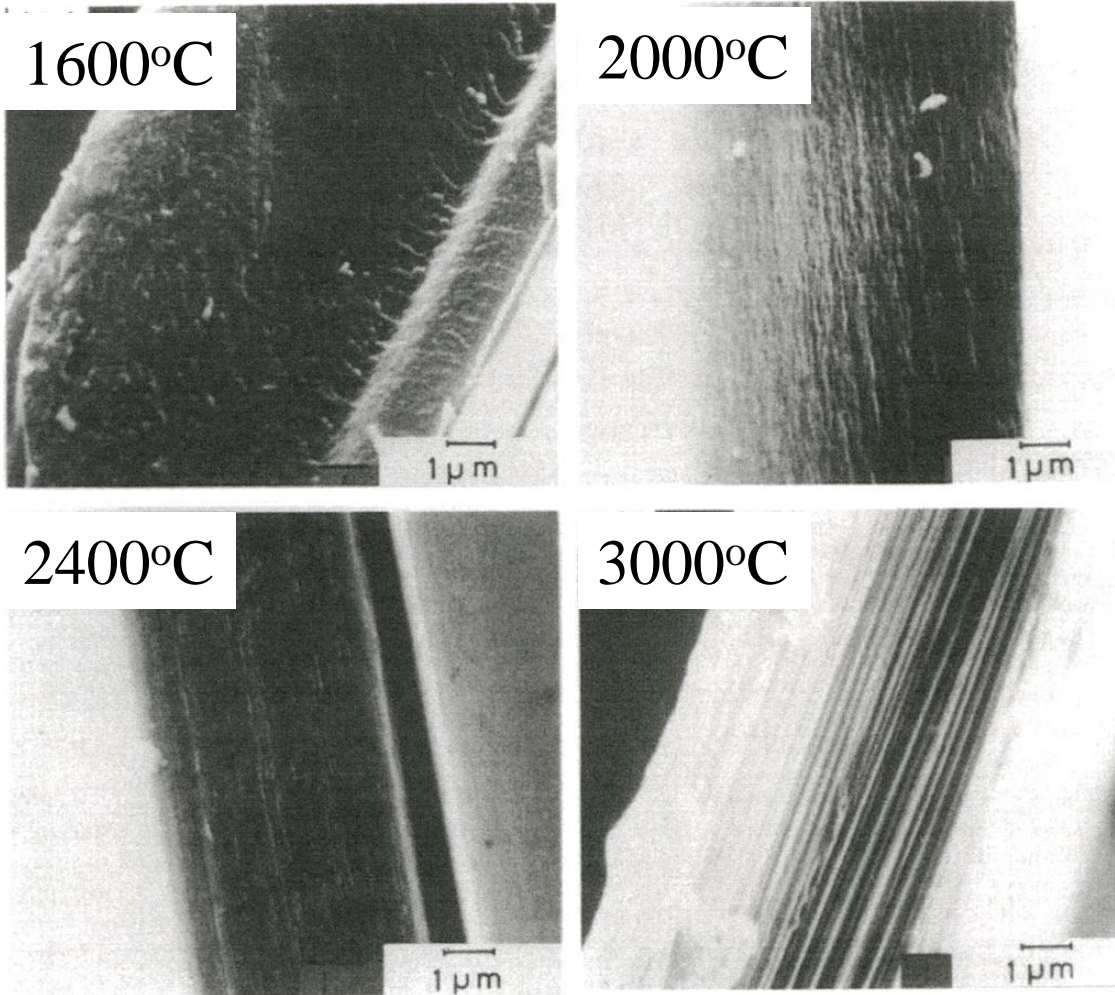




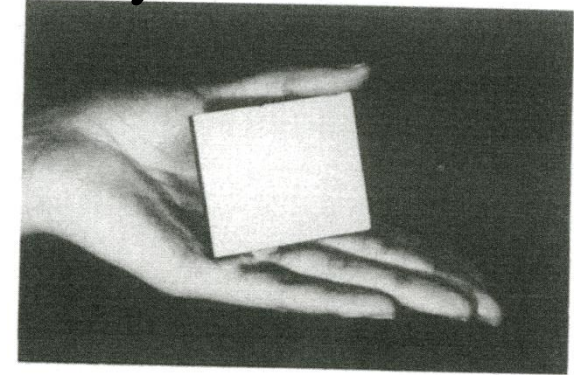
合成法には2種類あり、高圧(約5万気圧. 5070 bar)と高温(約1500°C)で作る高温高圧合成法と、低圧(約0.1気圧)のメタンと水素から成る原料ガスをプラズマ中で反応させ、約1000°Cの基板上に堆積させる気相合成法がある。

Graphite synthesis from polyimide films

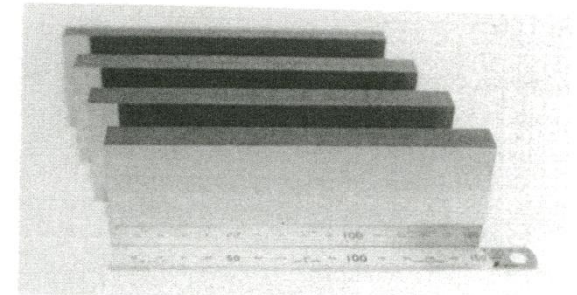
3000°C and 300 kg/cm² (294 bar, 290 atm, 30 MPa)



X-ray monochromator



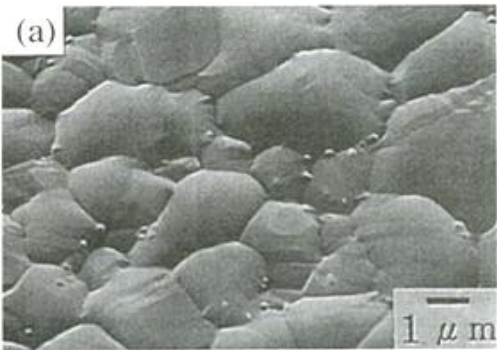
(a)



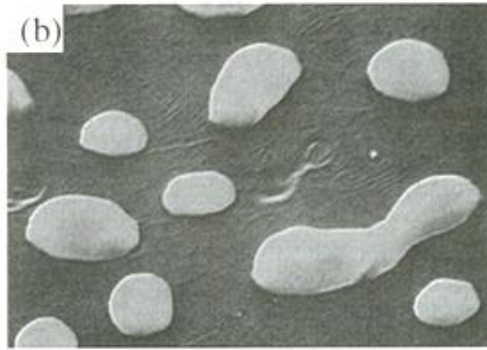
Neutron filter

Fig. 1. Cross-sectional views of heat-treated polyimide (Kapton®) by SEM observation; (a): 1600°C, (b): 2000°C, (c): 2400°C, (d): 3000°C.

Graphite Thin Film Formation by CVD on Ni/Quartz glass



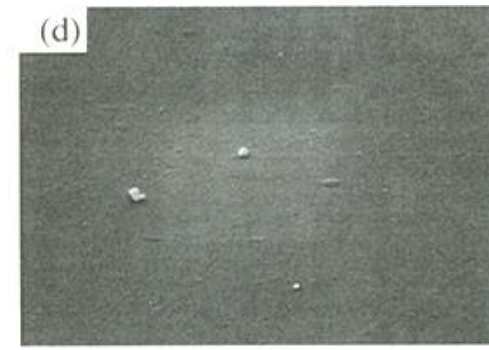
Ni (500 nm)



Ni (100 nm)

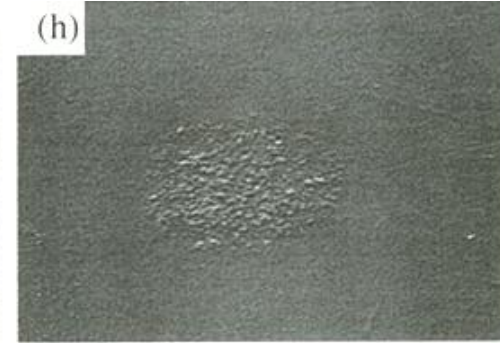
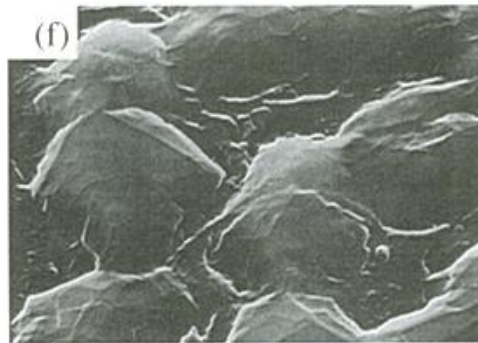
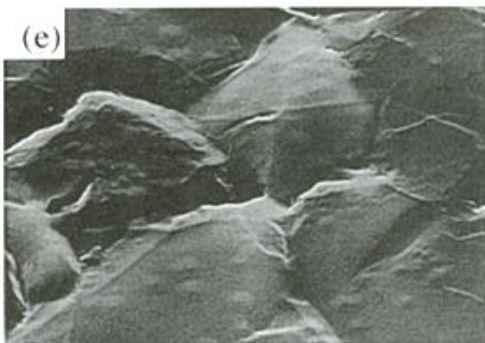


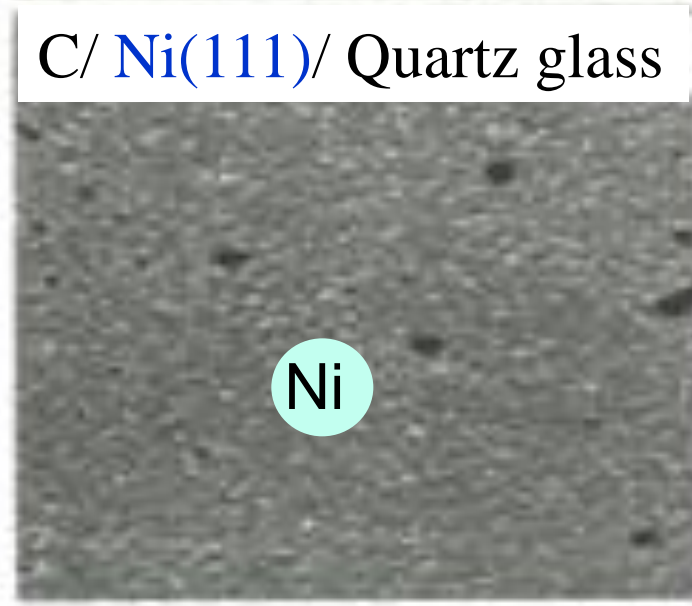
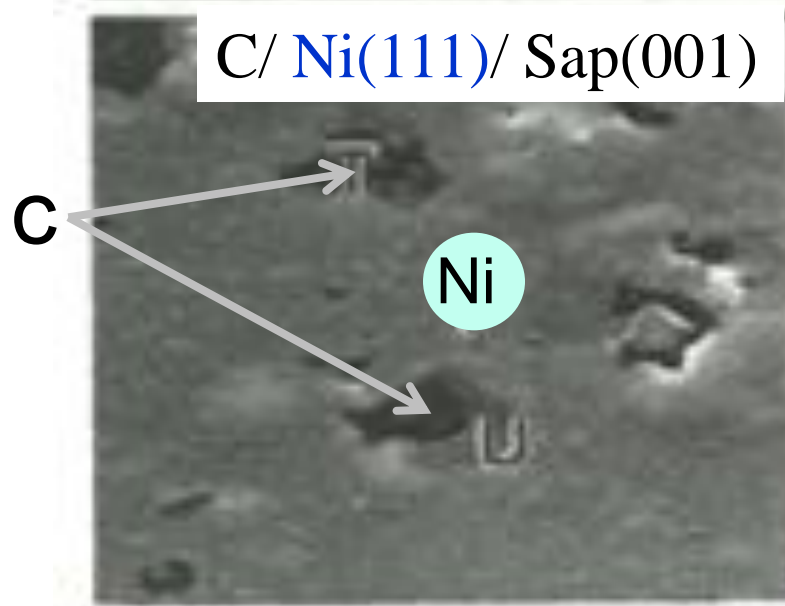
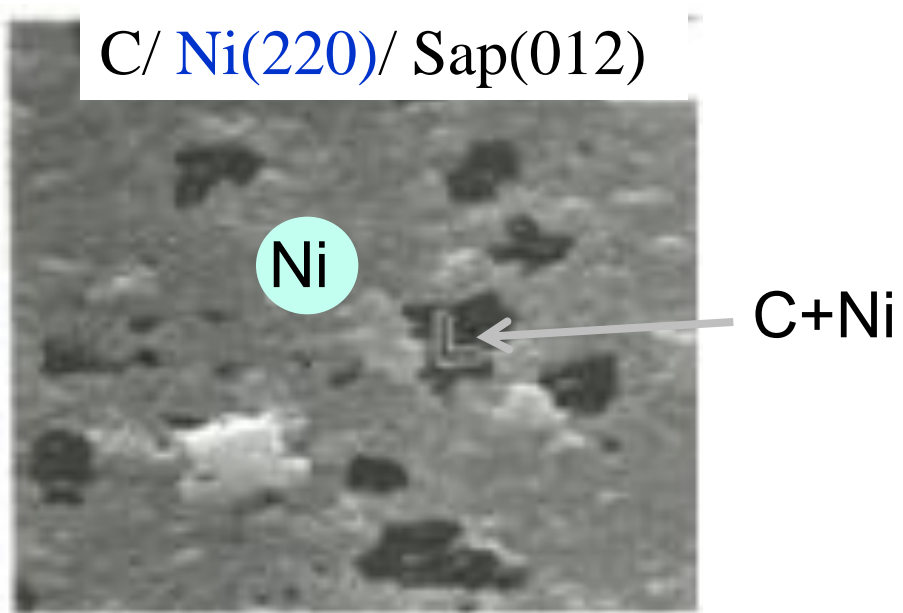
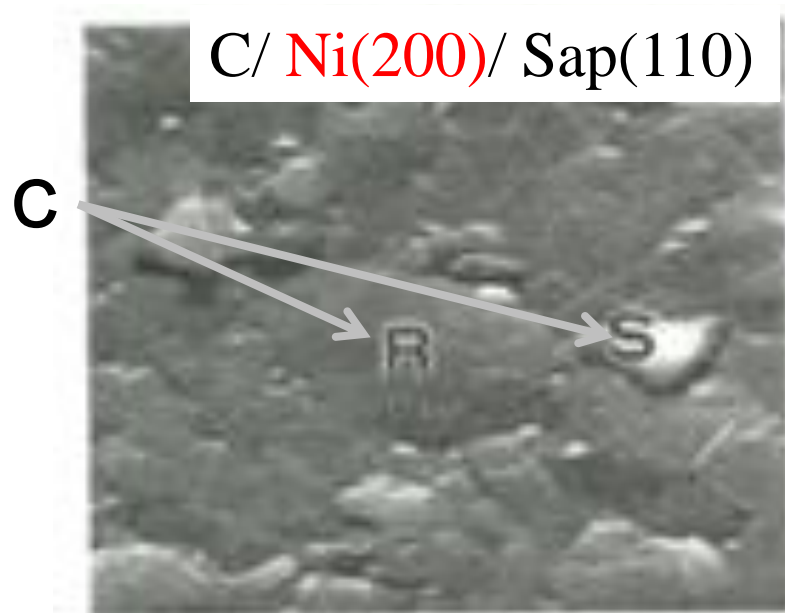
Ni (50 nm)



Ni (1 nm)

↓ CVD (1000°C)





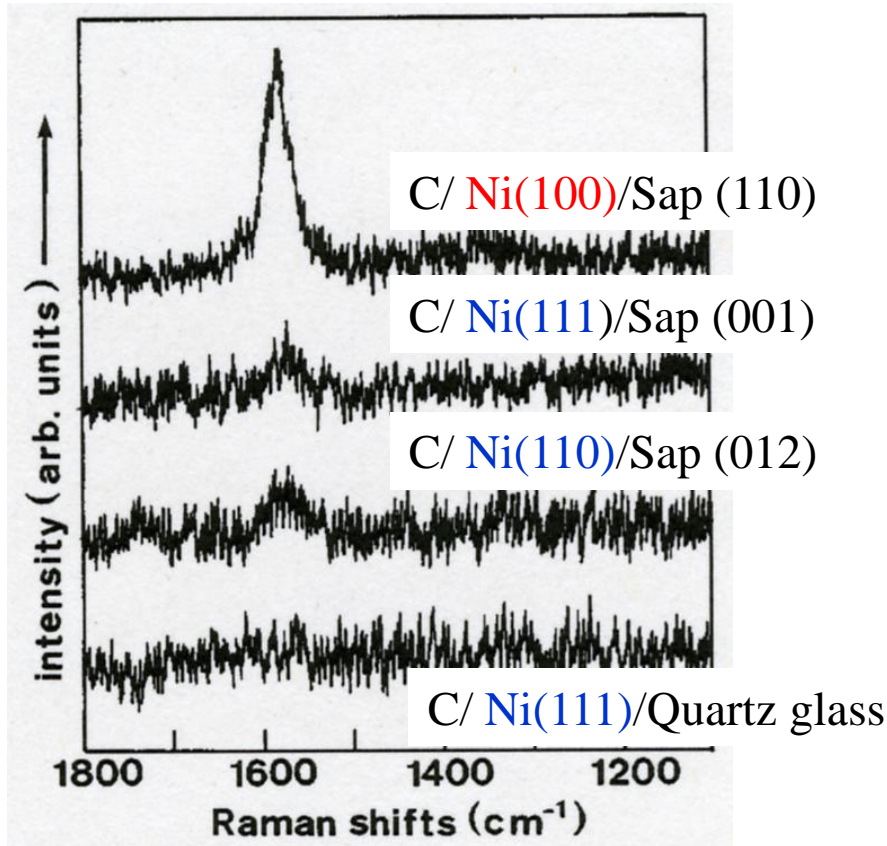
3 μm

CVD 700°C, 2h. 2-methyl-1,2'-naphthyl ketone
Ni film thickness: 50 nm

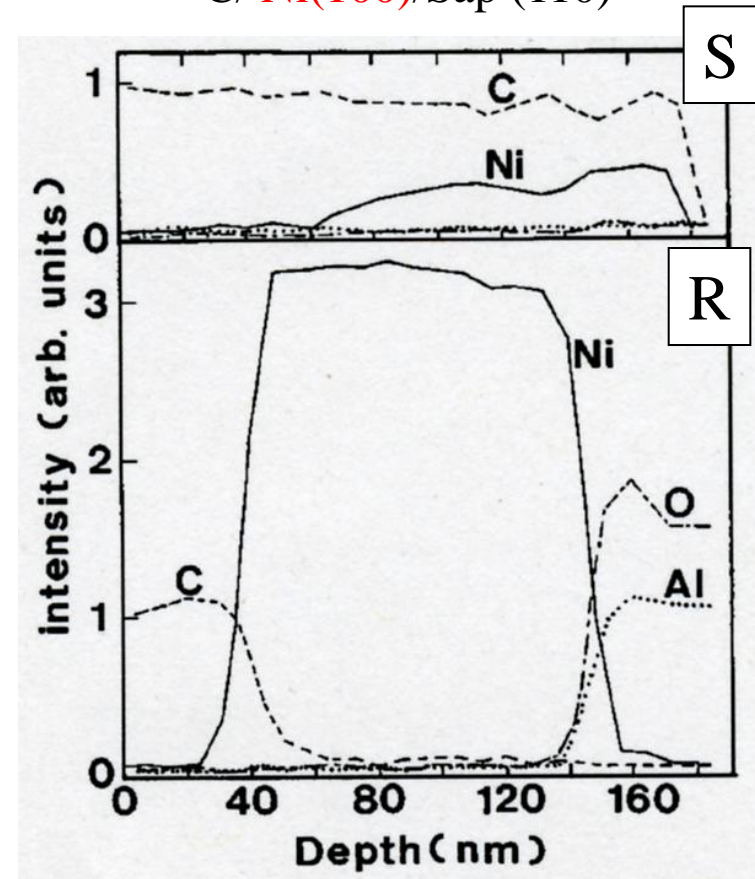
Yudasaka et al. J. Vac. Sci. Technol. A 1998.

Graphite formation on Ni(100) >> Ni(111), Ni(110)

C/ Ni(100)/Sap (110)



Raman scattering spectra

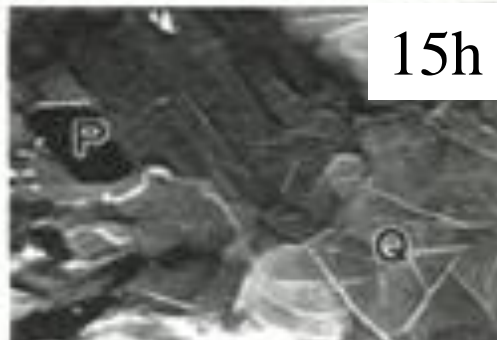
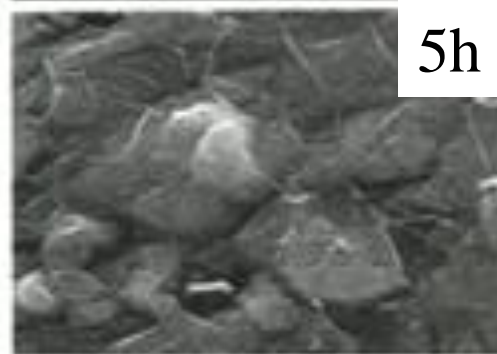
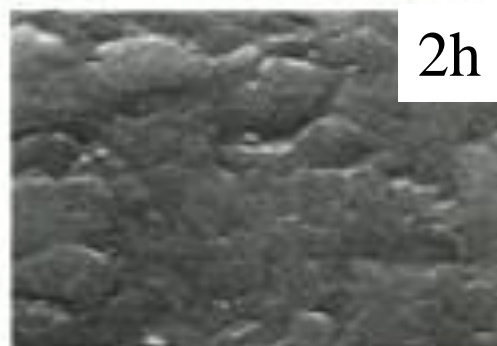
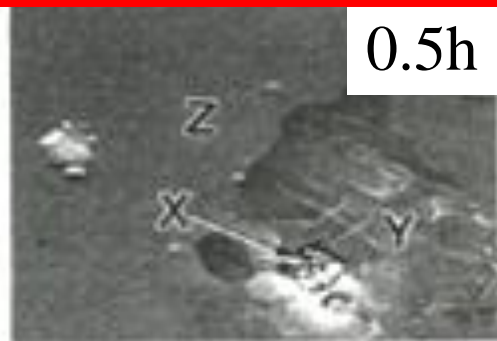


Selected Area Auger analysis
(Depth profiles of elements)

Material name		Nickel				
Composition		Ni				
Chemical formula weight		58.69				
System		Cubic				
Temperature (°C)		25				
a (Å), b (Å), c (Å)		3.5238(3)	3.5238(3)	3.5238(3)		
α (deg), β (deg), γ (deg)		90	90	90		
Unit cell volume (Å ³)		43.76				
Calculated density (g/cm ³)		8.91				
Z		4				
Space group		<i>Fm3m</i> (No.225)				
atom	site	g	x/a	y/b	z/c	B (Å ²)
Ni	$4a$	1	0	0	0	-

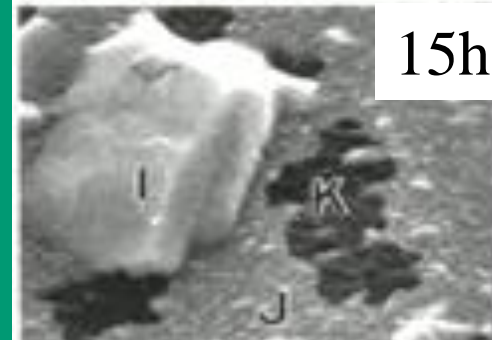
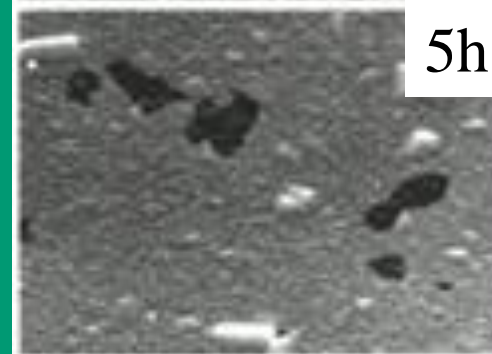
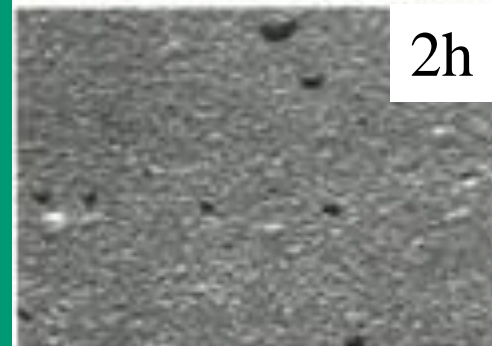
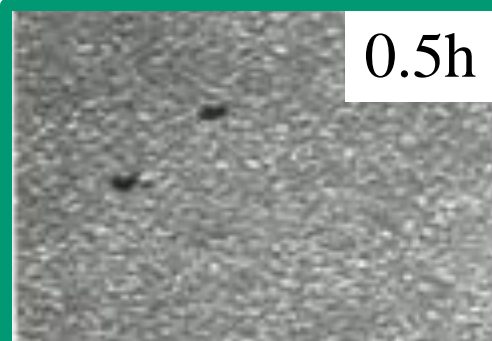
Reference: F.W. von Batchelder and R.F. Raeuchle, Acta Crystallographica, **7**, 464 (1954).

C/Ni(100)/Sap.



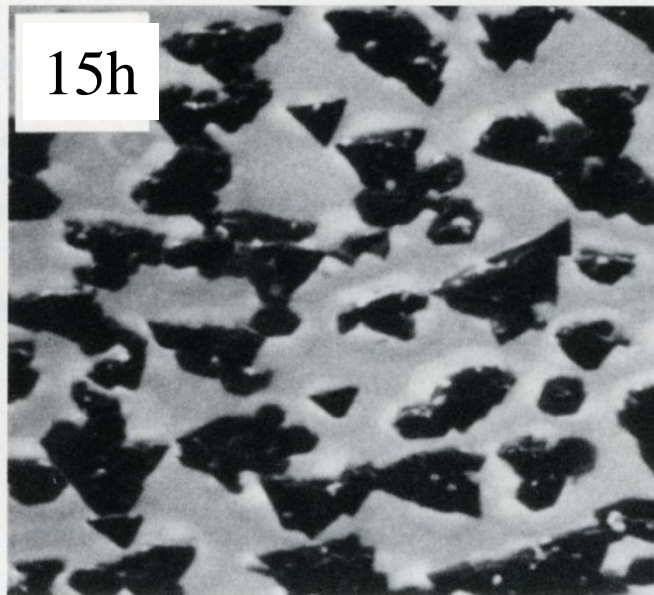
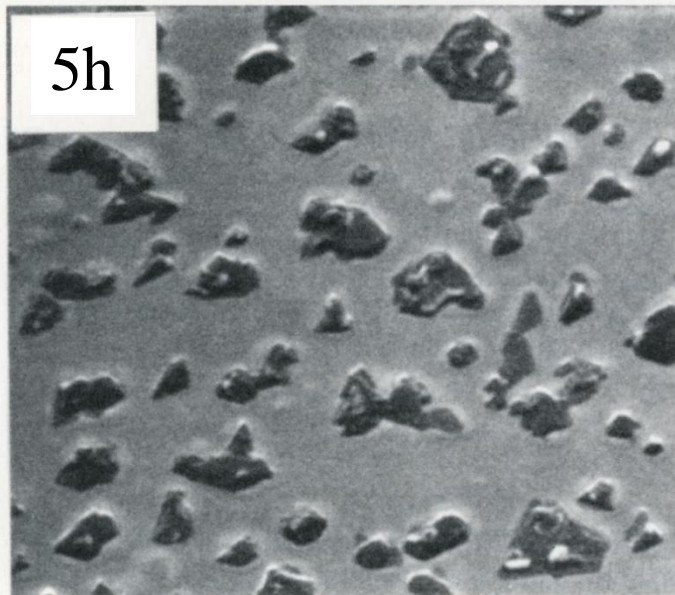
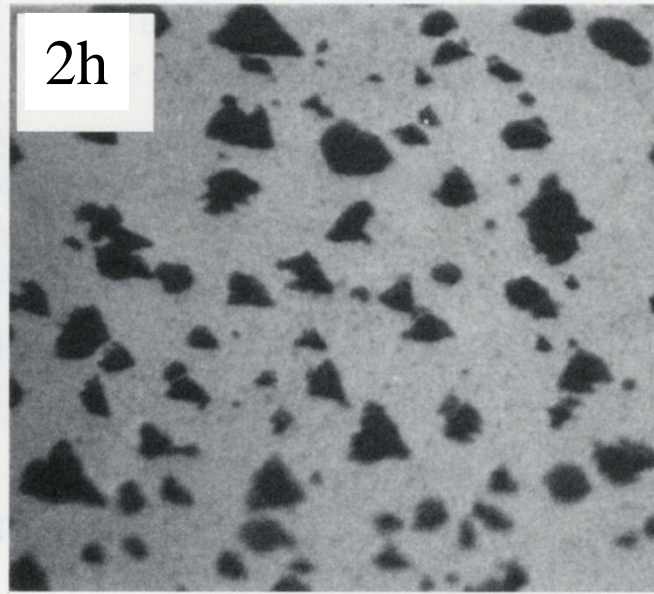
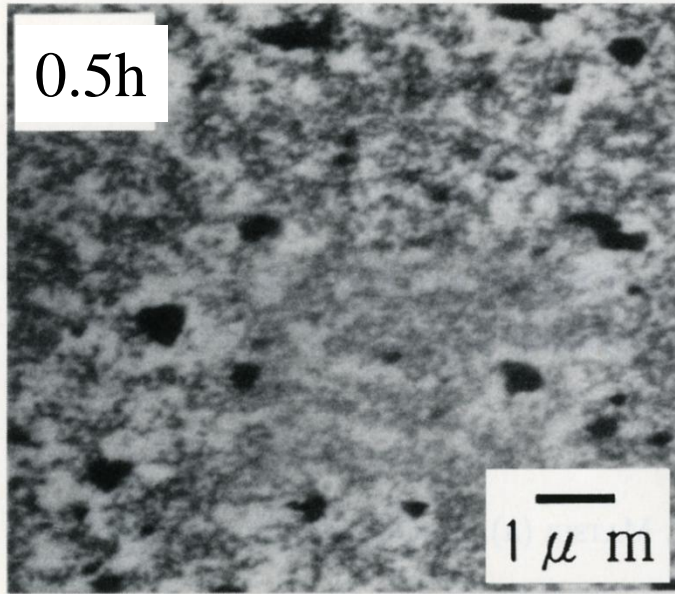
Yudasaka et al. *J. Vac. Sci. Technol. A* 1998.

C/Ni(111)/Sap.



3 μm

Graphite/Pt(111)/Sapphire(110)



CVD 900°C,
Pt 50 nm
Pt(111)
Sapphire (110)

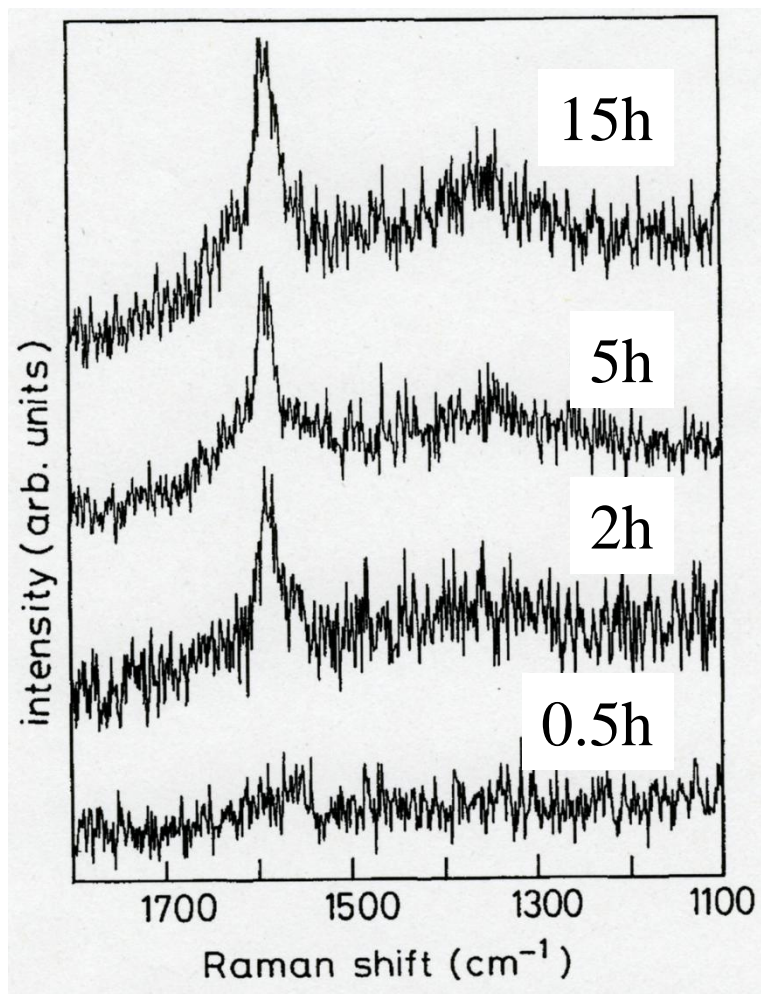
time (h)	0.5	2	5	15	2 + 18
d_{002} (nm)	(0.3373)	0.3356	0.3352	0.3353	0.3358
Δ_{002} (°)		0.37	0.26	0.18	0.25
δ_{222} (°)	(0.33)	0.27	0.25	0.28	0.18
d_{222} (nm)	0.1130	0.1129	0.1127	0.1127	0.1131
Δ_{222} (°)	0.20	0.20	0.22	0.19	0.22
δ_{222} (°)	0.11	0.14	0.12	0.13	0.14

Pt film: $d_{222}=0.1129$ nm \rightarrow 0.3387 nm

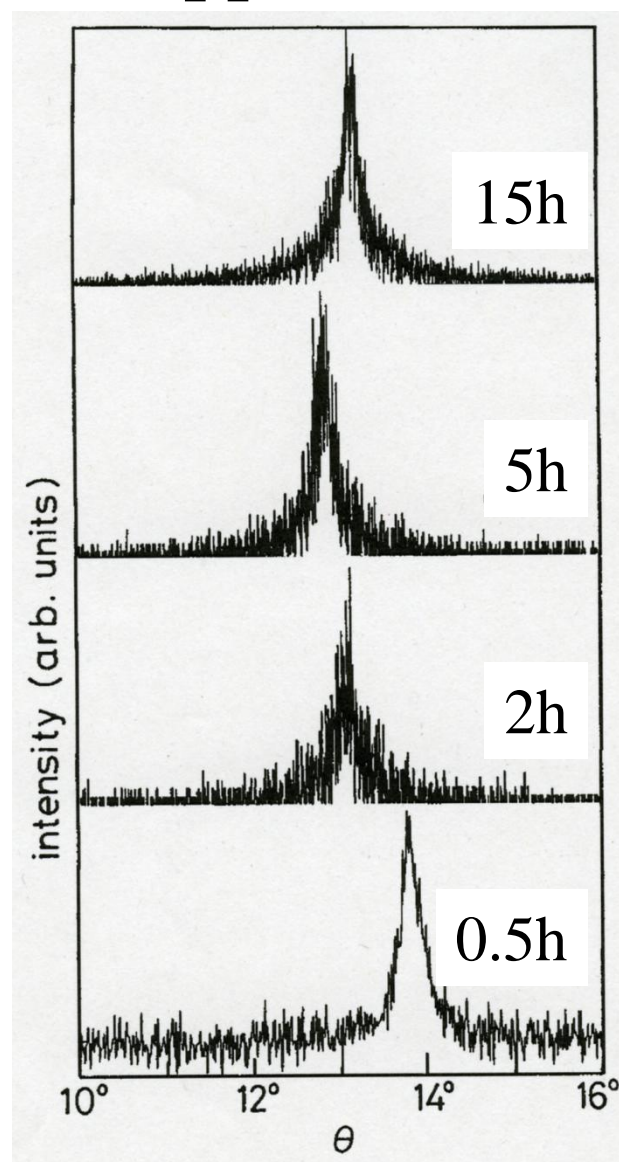
Pt crystal: $d_{222}=0.11325$ nm \rightarrow 0.33975 nm

Material name		Platinum				
Composition		Pt				
Chemical formula weight		195.08				
System		Cubic				
Temperature (°C)		18				
a (Å), b (Å), c (Å)		3.924	3.924	3.924		
α (deg), β (deg), γ (deg)		90	90	90		
Unit cell volume (Å ³)		60.4				
Calculated density (g/cm ³)		21.5				
Z		4				
Space group		<i>Fm3m</i> (No.225)				
atom	site	g	x/a	y/b	z/c	B (Å ²)
Pt	$4a$	1	0	0	0	-

Graphite/Pt(111)/Sapphire(110)

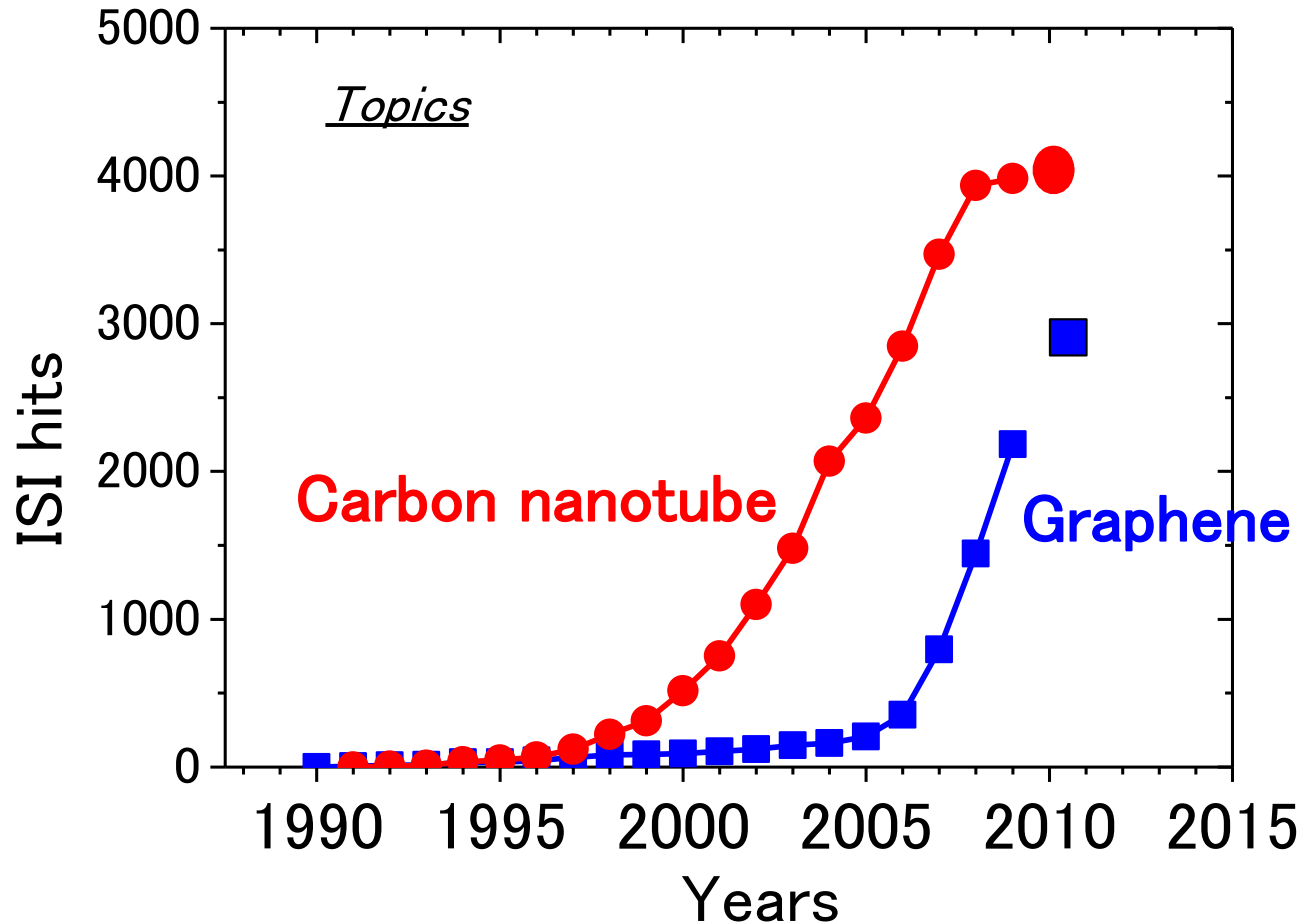


Raman spectra



X-ray diffraction rocking curves

Studies on Graphene: Quickly Increasing



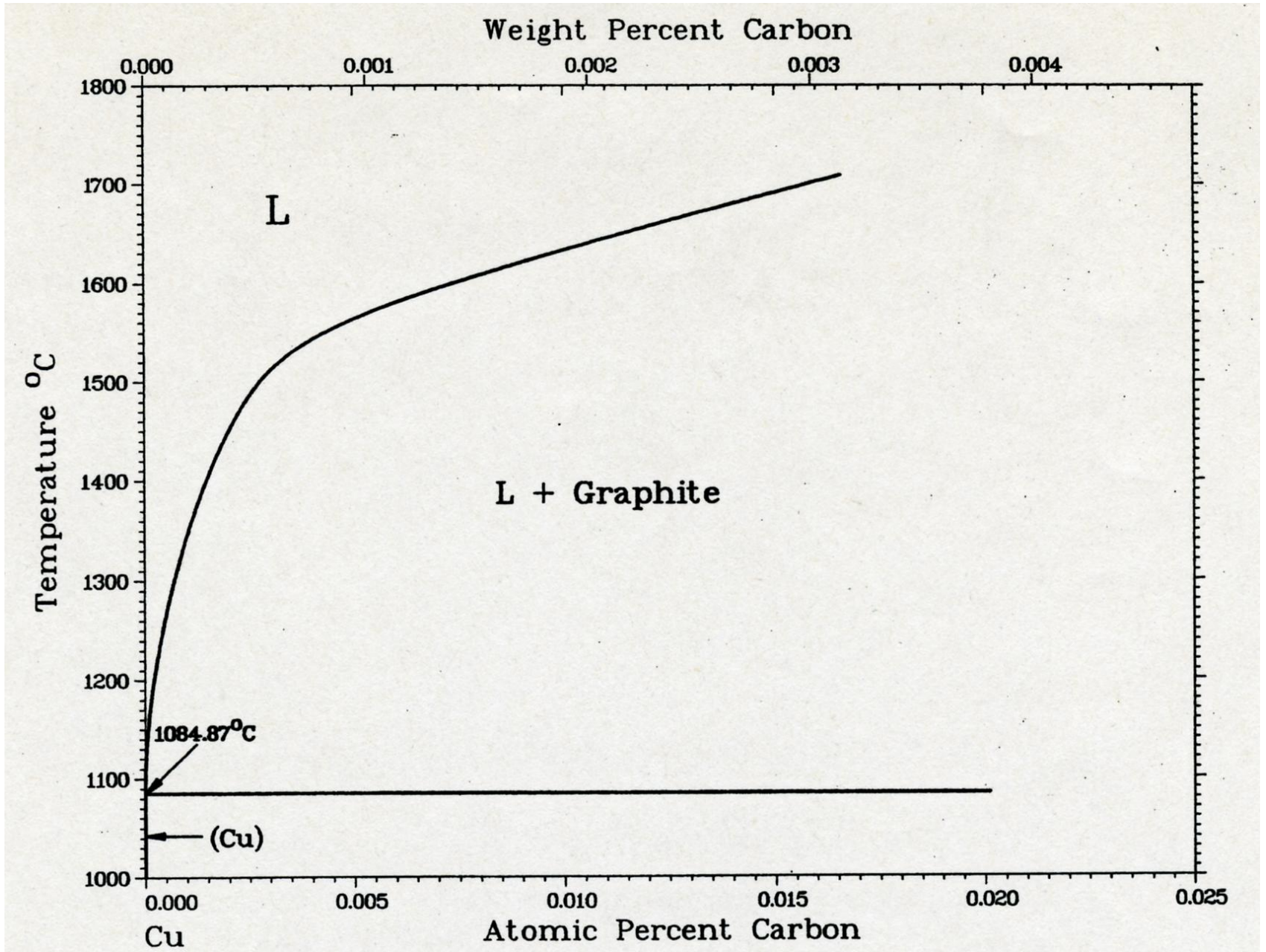
2010 (July) 1446
2009 2185
2008 1444
2007 796
2006 352
2005 205
2004 161
2003 147
2002 119
2001 106
2009 90
1999 85
1998 83
1997 64
1996 44
1995 31
1994 30
1993 15
1992 12
1991 5

How to obtain graphenes?

~2005 Peeling

Recently CVD on Cu

Cu-C Phase diagram

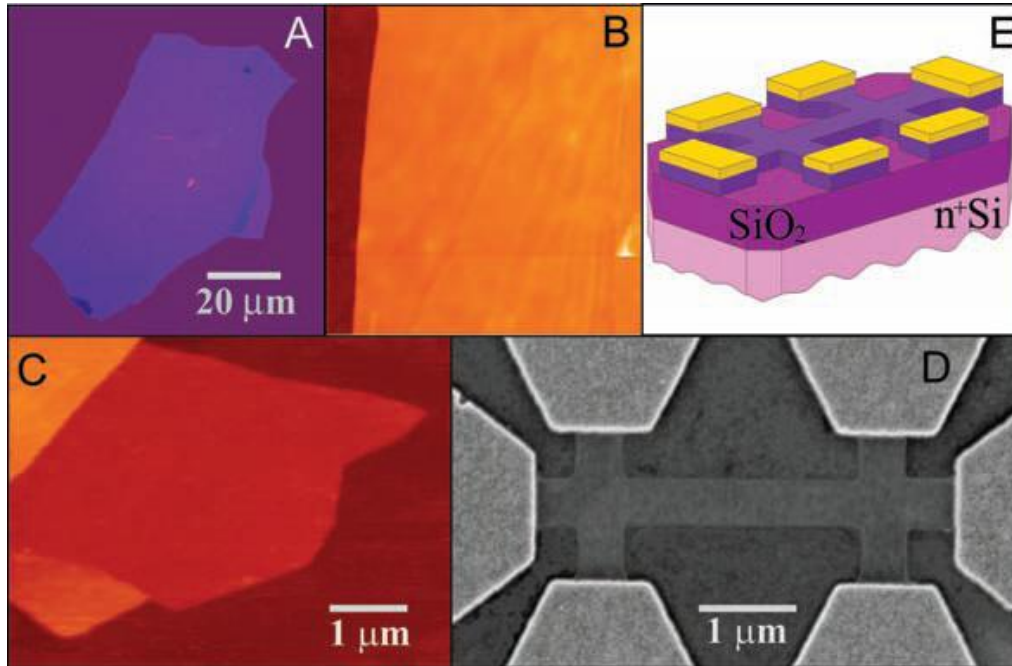


- Electric field effect in atomically thin carbon films

Novoselov, Geim, et al. Science 2004

- Two-dimensional gas of massless Dirac fermions in graphene.

Novoselov, Geim, et al. Nature 2005

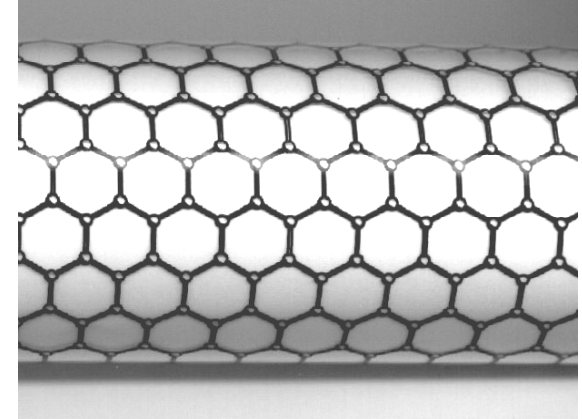
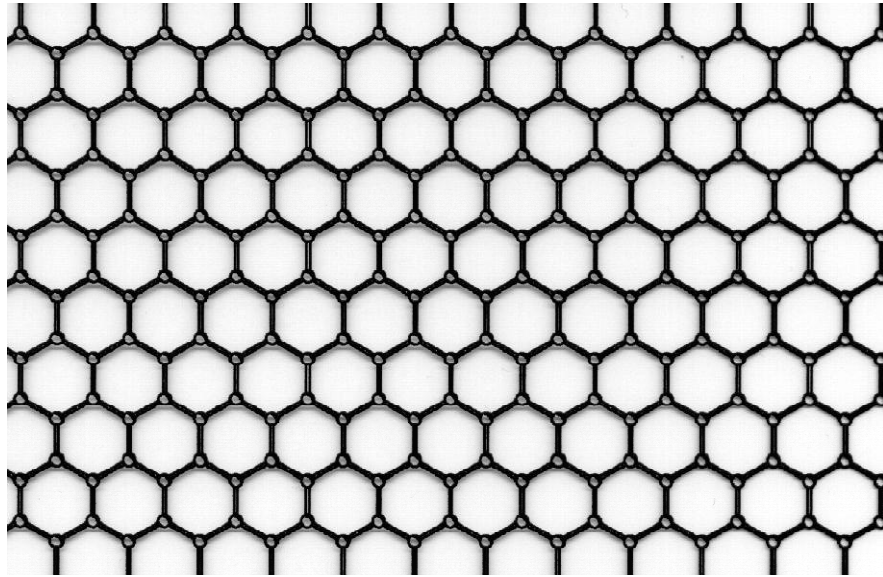


(Novoselov et al Science 2004)

Room temperature mobility: $10,000 \text{ cm}^2/\text{Vs}$. Carrier concentration (electron, hole): 10^{13} cm^{-2} graphite . (GaAs-based HEMT (2D-gas): 10^{12} cm^{-2} , $6000 \text{ cm}^2/\text{Vs}$)

Graphene films: Repeated **peeling** of highly oriented pyrolytic graphite.

グラファイトシート 1枚からなる円筒が構造単位



単層炭素ナノチューブ (Single-wall carbon nanotube, SWNT)

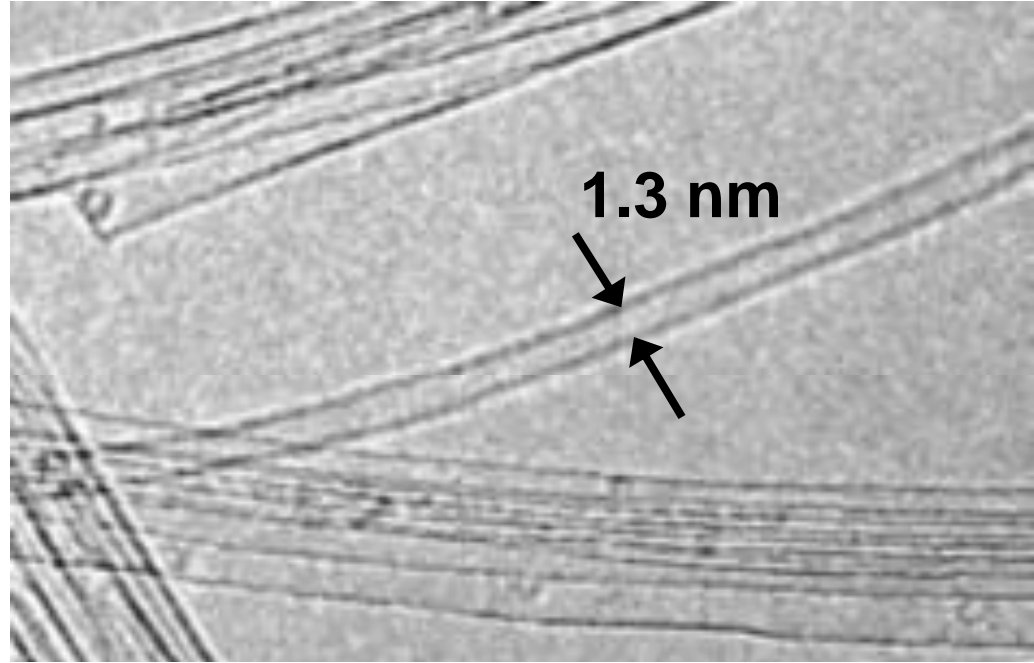
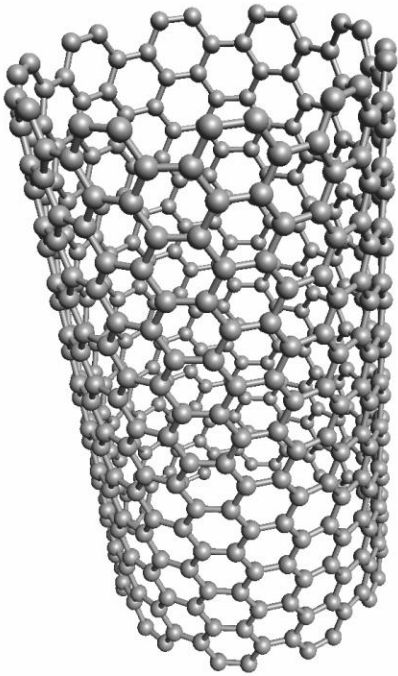
多層炭素ナノチューブ (Multi-wall carbon nanotube, MWNT)

単層カーボンナノホーン (Single-Wall carbon Nanohorn, SWNH)

1993 : Single-Wall Carbon Nanotubes Were Found.

S. Iijima, T. Ichihashi, *Nature* 363, 603, 1993.

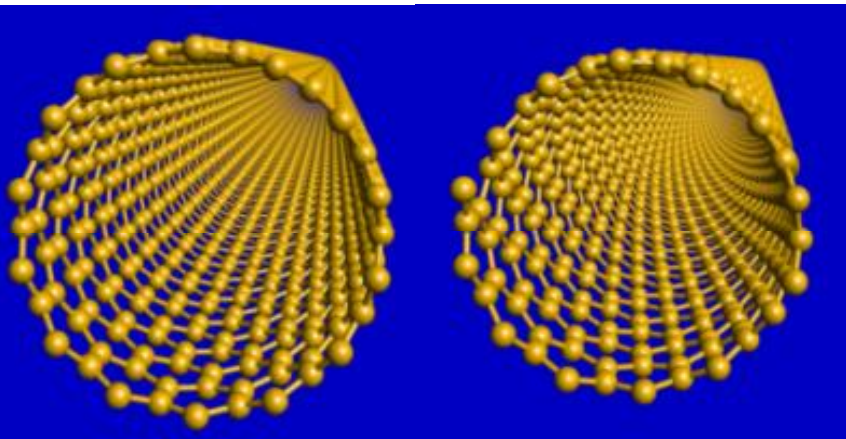
D. S. Bethune et al. *Nature* 363, 605, 1993.



A graphene sheet forms a cylinder.

Diameter : 1.3 nm (0.4 ~ 2 nm)

Length : Micrometer order



Φ 1.3 nm: 40 C-atoms at edge

Carbon Nanotube Research

- 1960 Multi-Wall Carbon Tubes with Micrometer-Order Diameters (R. Bacon)
- 1985 C_{60} (Kroto, Smalley et al.)
- 1991 Multi-Wall Carbon Nanotubes Structure: Seamless Cylinder of Graphene Sheets (Iijima)
- 1992 Theoretical Prediction of Electronic Structure of SWNT (Hamada et al.)
- 1993 Synthesis and Confirmation of SWNTs (Iijima et al.), (Bethune)
- 1995 Large Scale Synthesis of SWNTs (Smalley et al.)
- 1997 Electric Properties Measurement of Individual SWNT (Dekker et al.)
- 1998 FED (Y. Saito)
- 1998 Research on CNT Field Effect Transistors (Dekker et al.), (Avouris et al.)
- 1999 SWNHs
- 2001 Logic Circuit (Dekker et al.)

CVD growth of SWNT

Research on the bio applications

多層カーボンナノチューブ (MWNT)

製法を大別すると・・・

金属触媒を用いる： 気相流動法、CVD法、アーク法

金属触媒を用いない： アーク法、HFプラズマ法

多層カーボンナノチューブのターゲット用途 (樹脂複合材料分野)

機械的応用分野
(強度、弾性率等)

長期

高強度構造部材
自動車外装
(バンパー等)

電磁波遮蔽材
放熱部品等

導電性フィルム
透明導電性薄膜
シート、マット等

機能的応用分野
(電気伝導性・熱伝導性)

短・中期

導電性塗料
導電性インキ
コーティング材

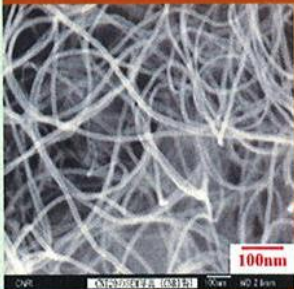
自動車外板
(フロントフェンダー
アタパネ等)

導電性接着剤
導電性シール剤

ウェハキャリア
HDDトレイ
LCDトレイ
ICトレイ等

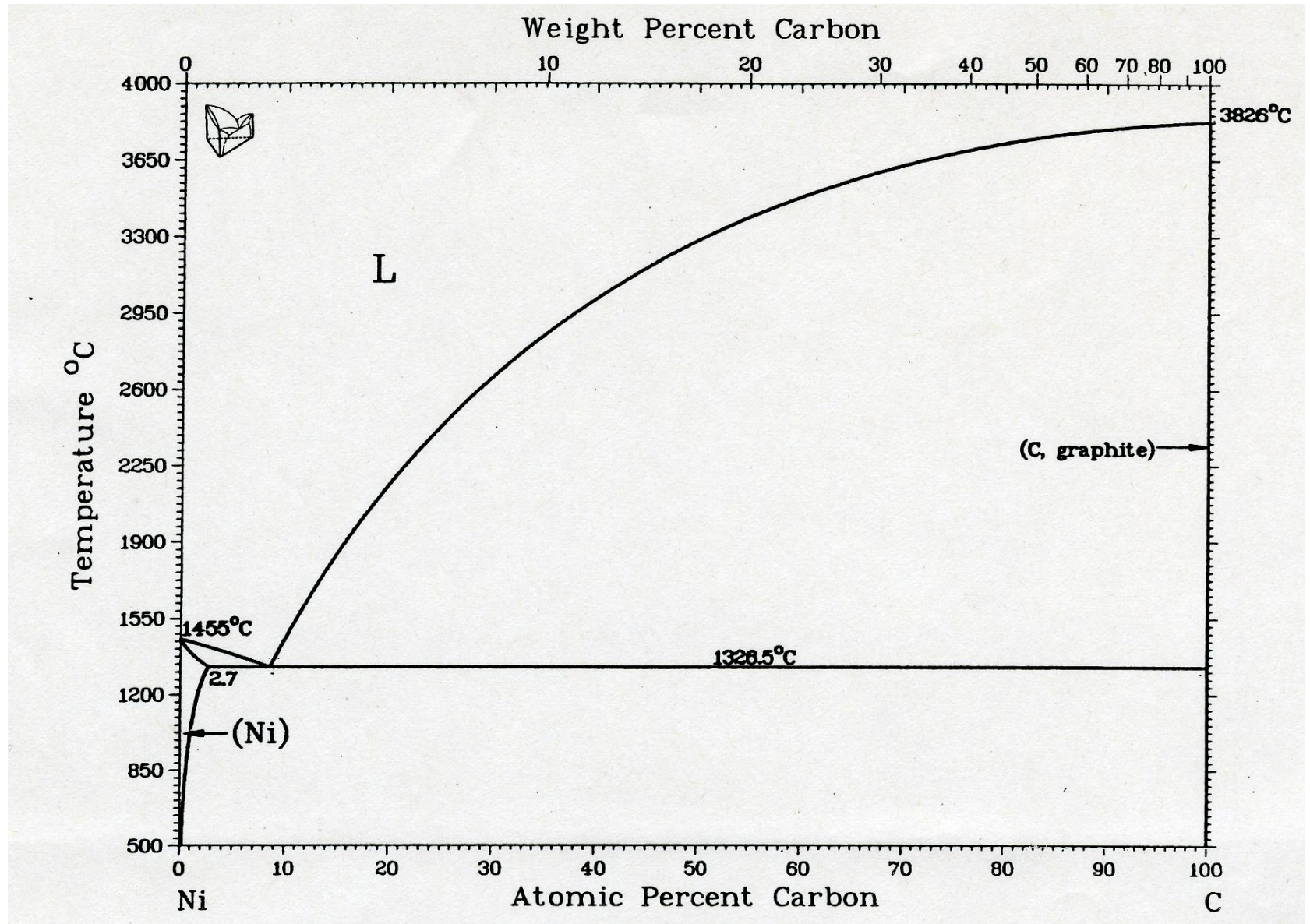
マスタバッチ/コンパウンド

多層カーボンナノチューブ粉末



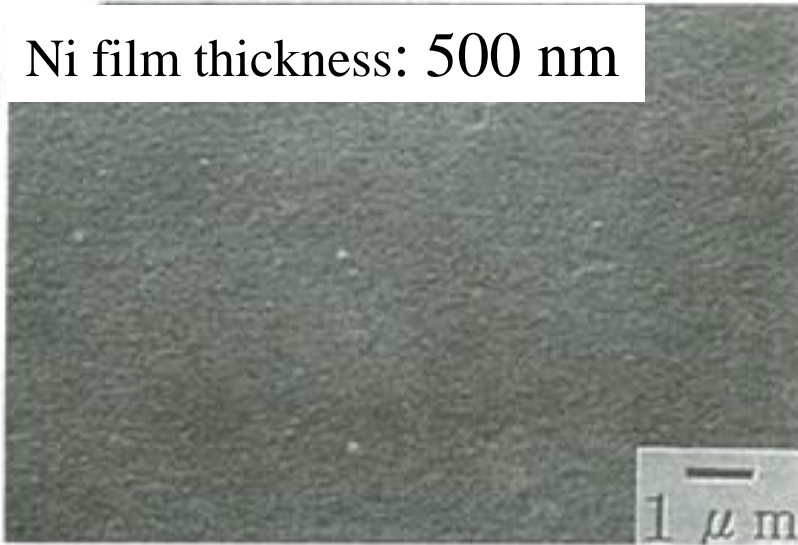
三井物産

Metal-Carbon Phase Diagram

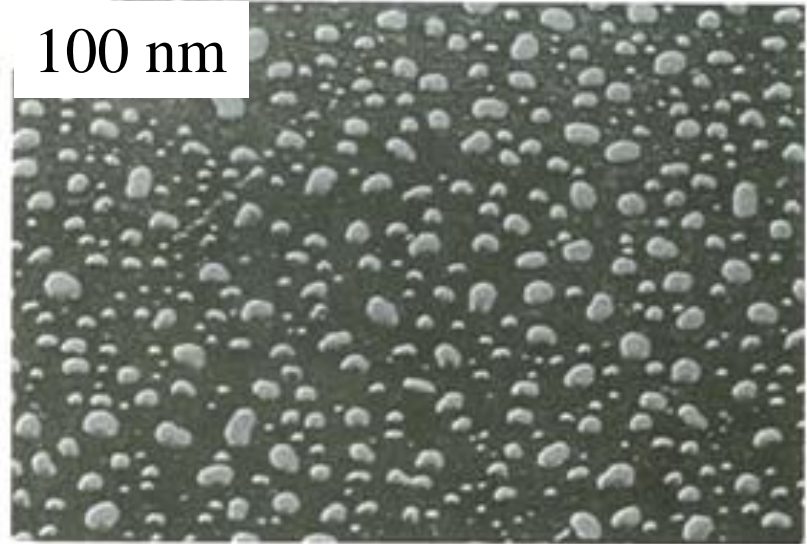


After heat treatment at 700°C

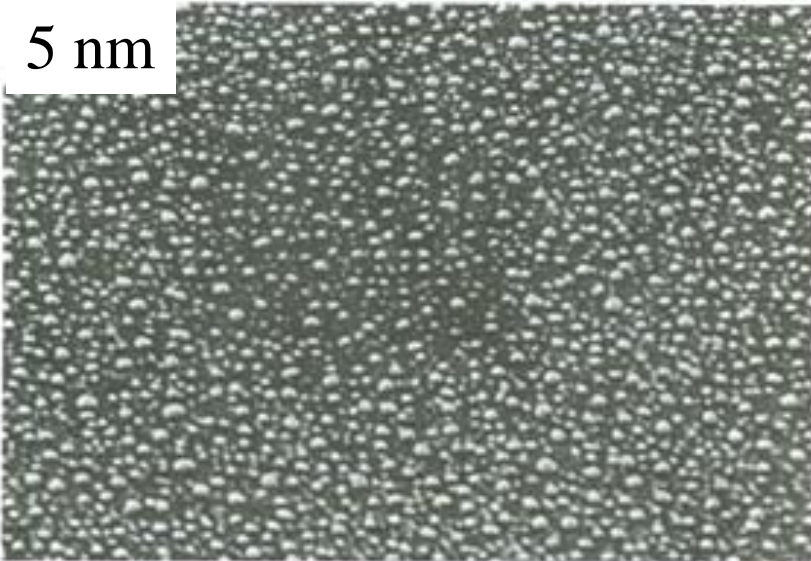
Ni film thickness: 500 nm



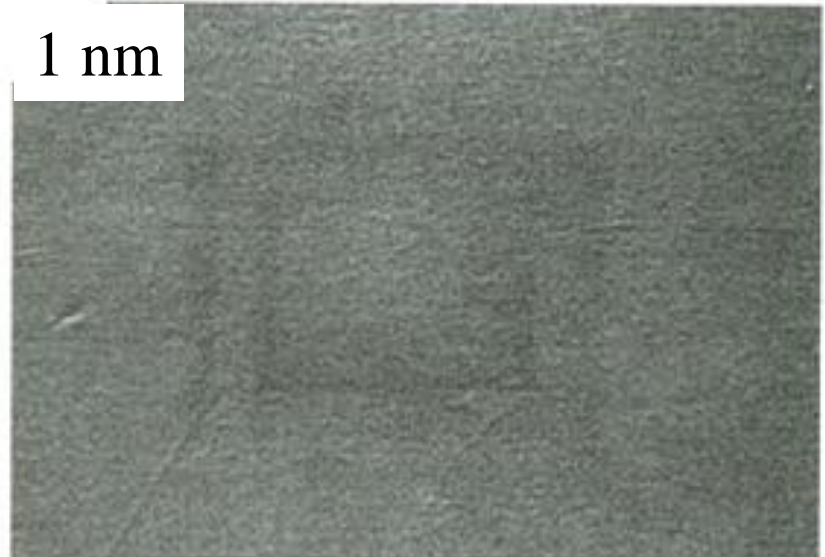
100 nm



5 nm

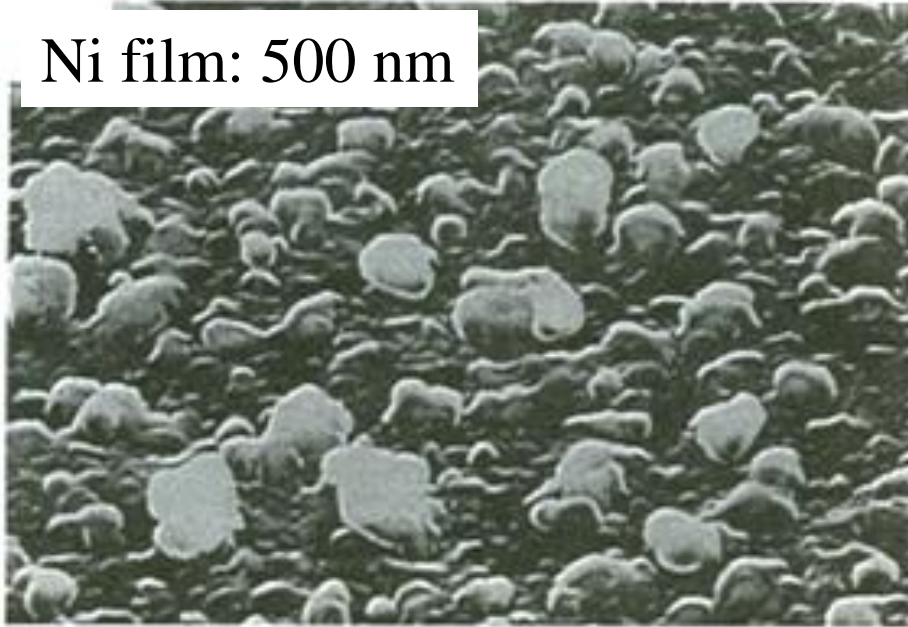


1 nm

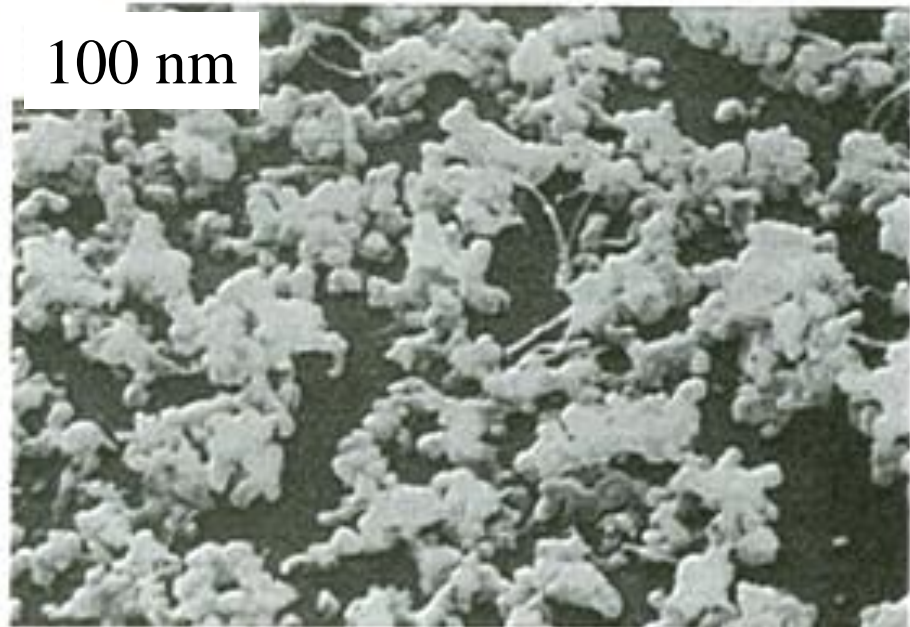


After CVD at 700°C

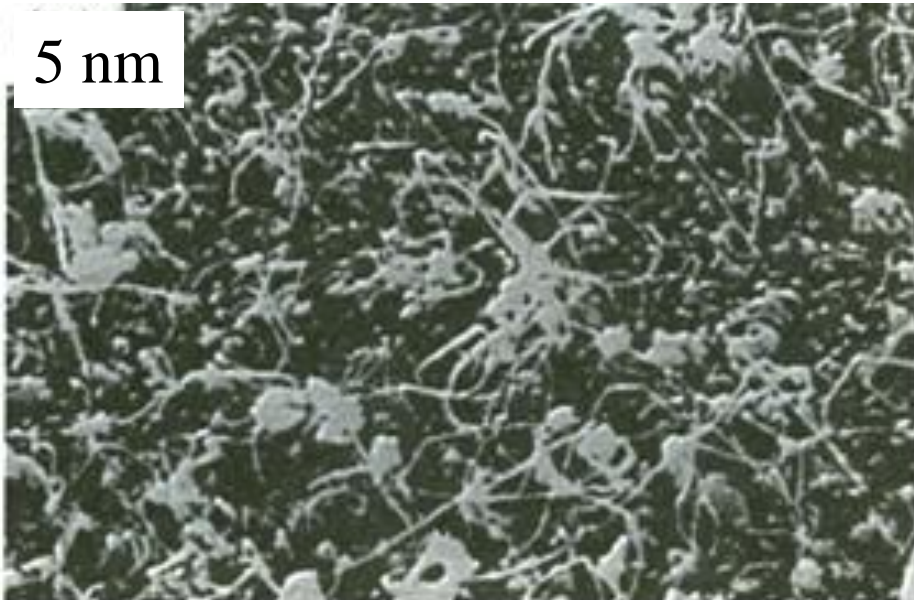
Ni film: 500 nm



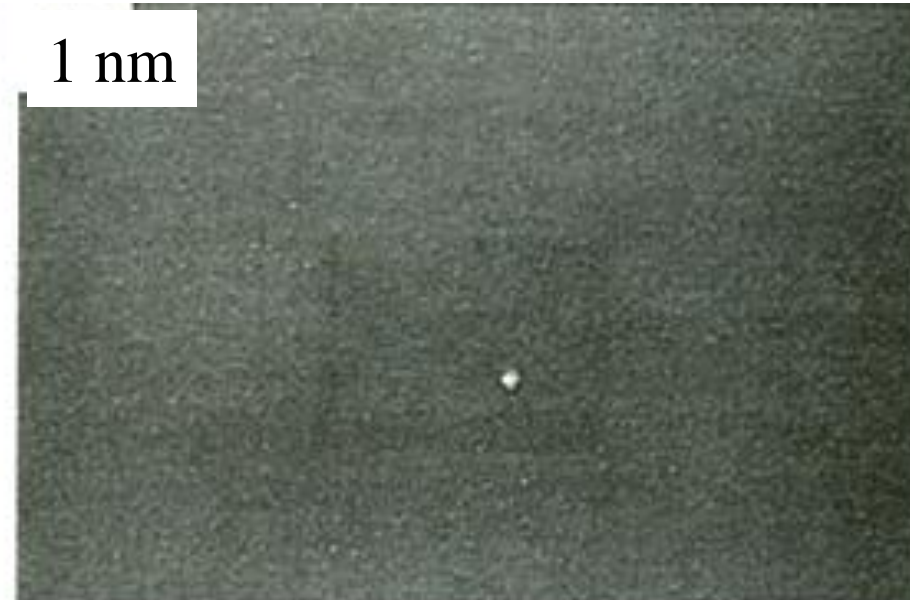
100 nm

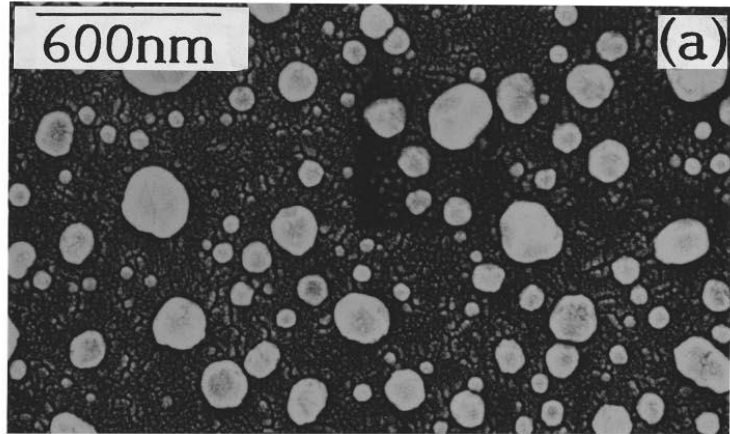


5 nm

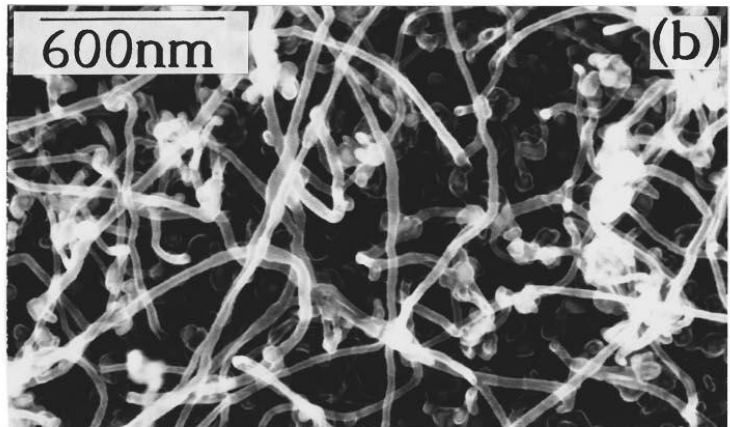


1 nm

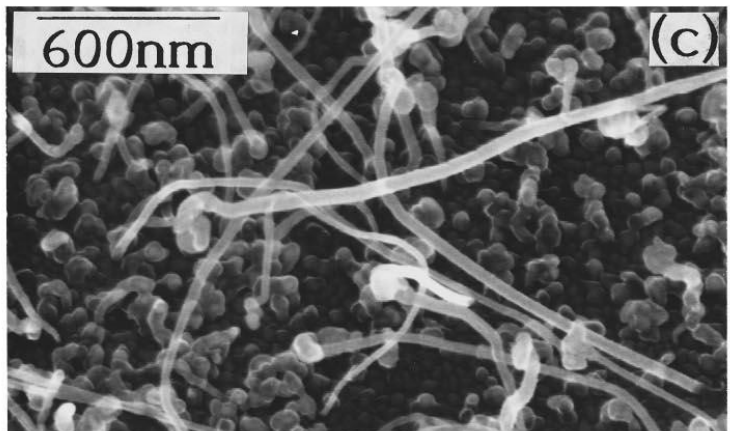




Thermal annealing
Ni films/glass \rightarrow Ni particles

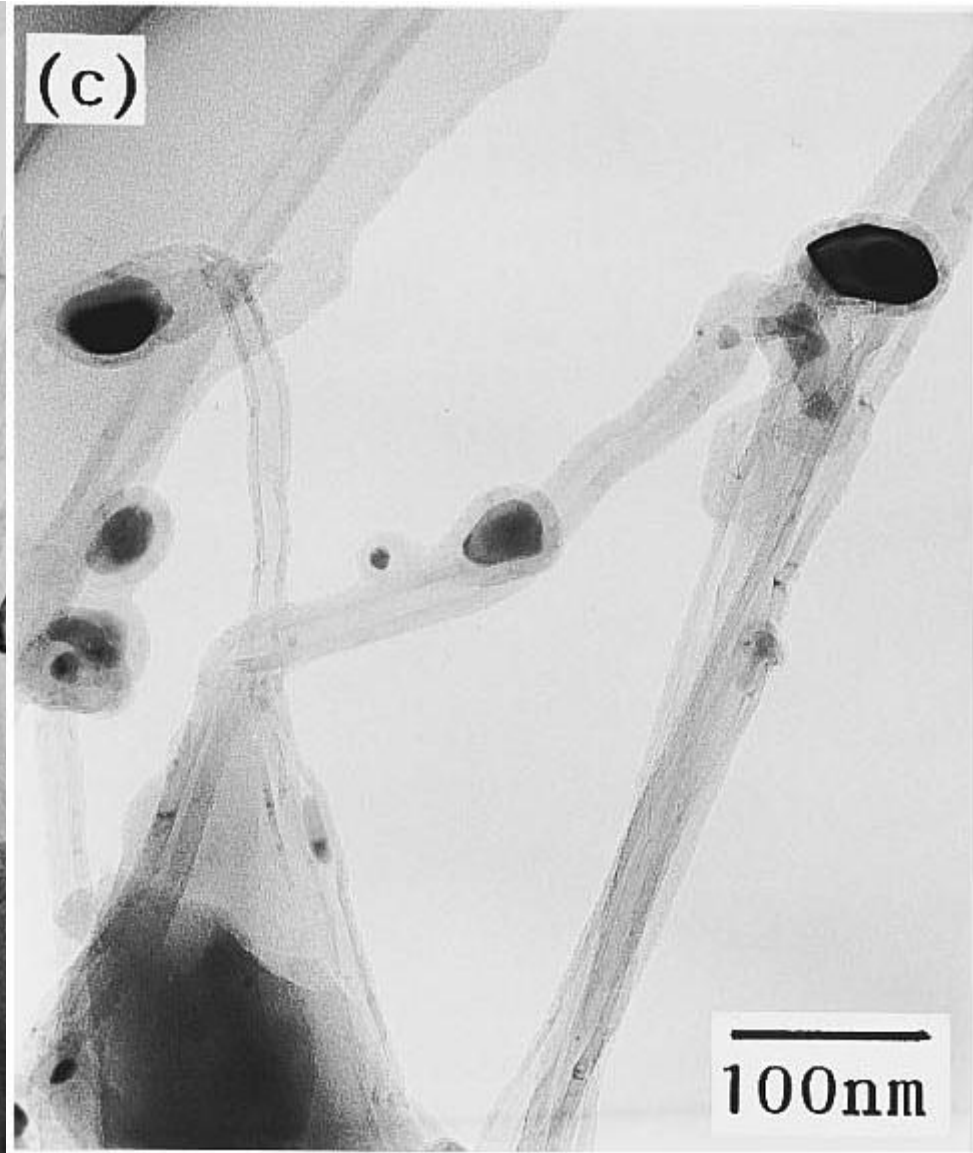
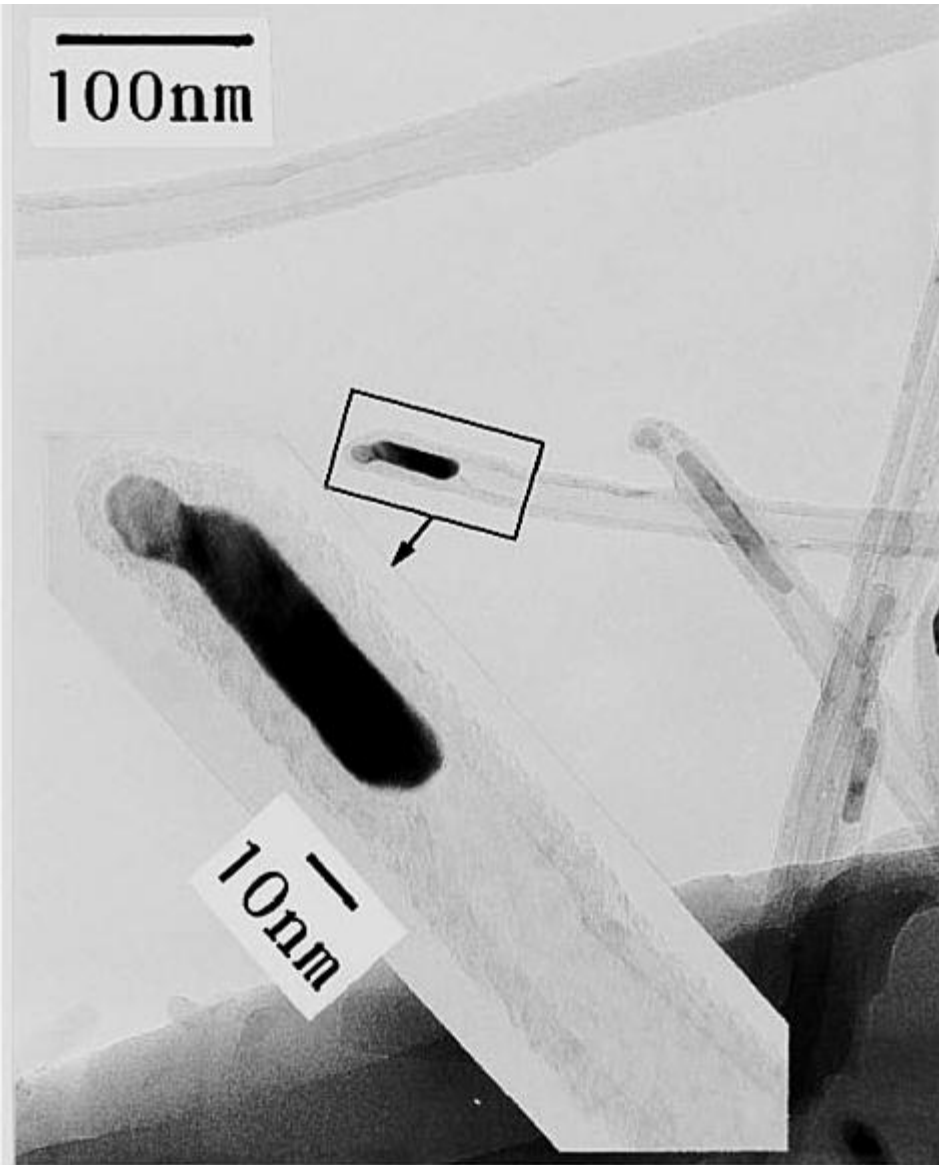


Chemical vapor deposition at 700°C
for 5 hours. Carbon source: Organic
molecules (2-methyl-1, 2'-naphthyl ketone)

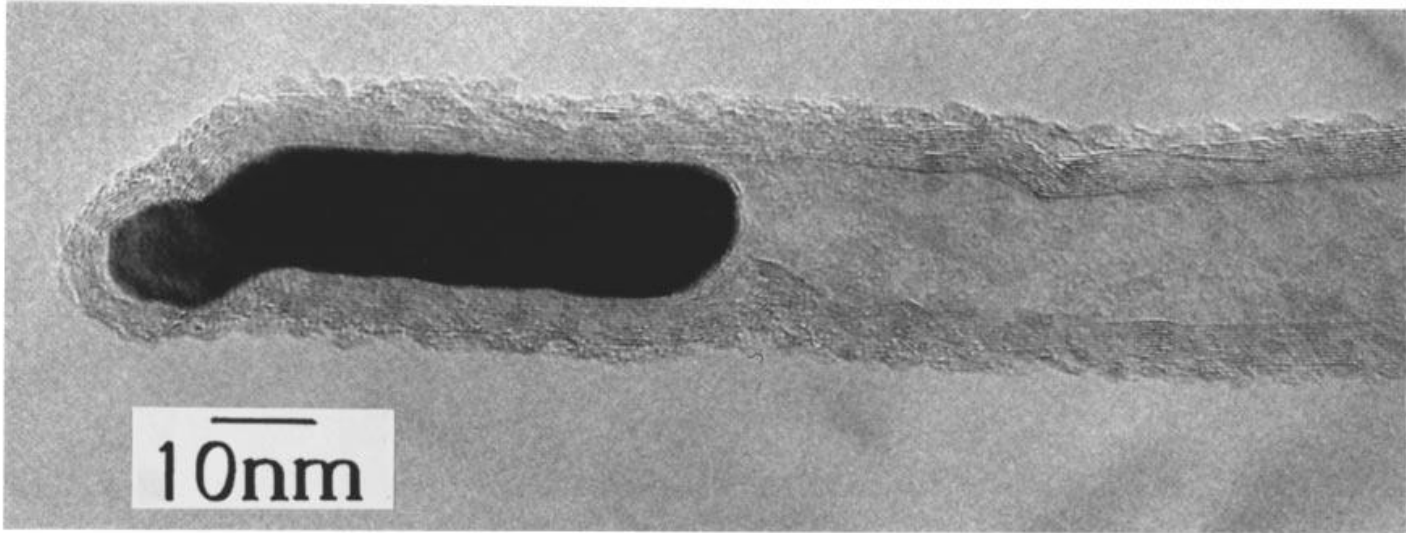


Chemical vapor deposition at 600°C
for 5 hours

MWNT growth nucleation depending on Ni particle sizes



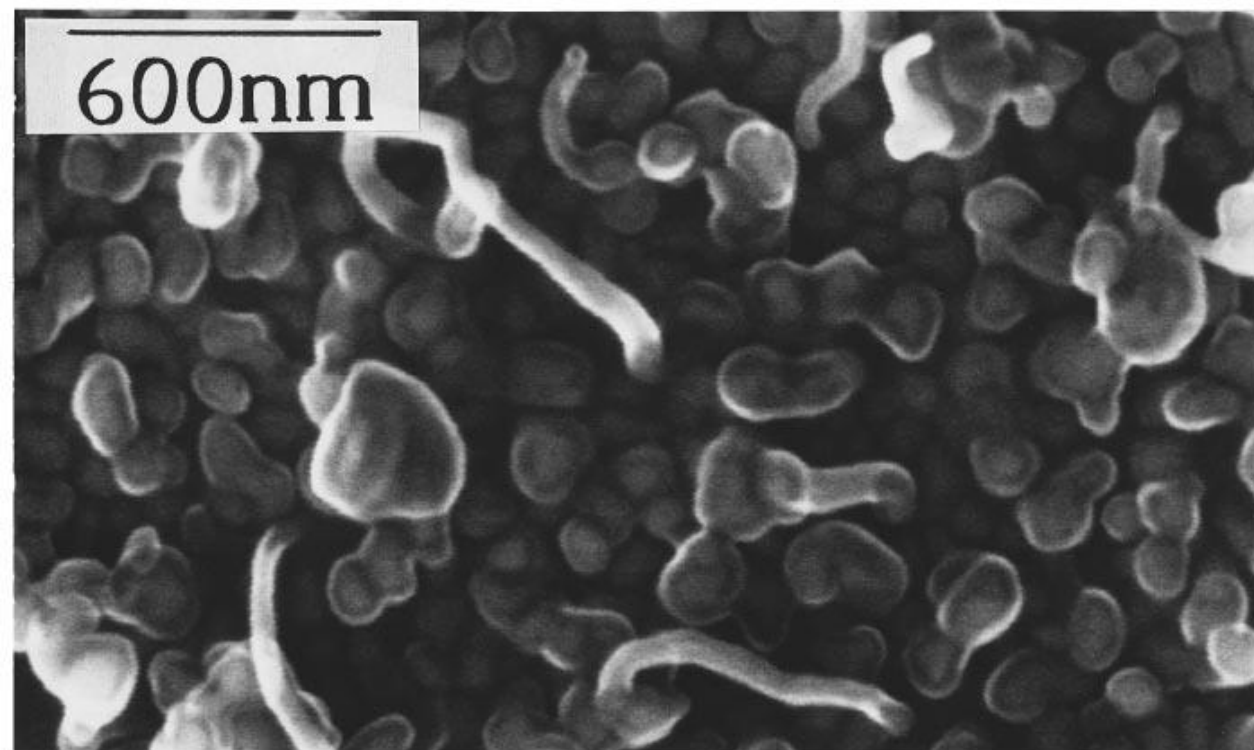
How to explain?



CVD at 700°C for 5 hours

Yudasaka et al, APL 1997

600nm



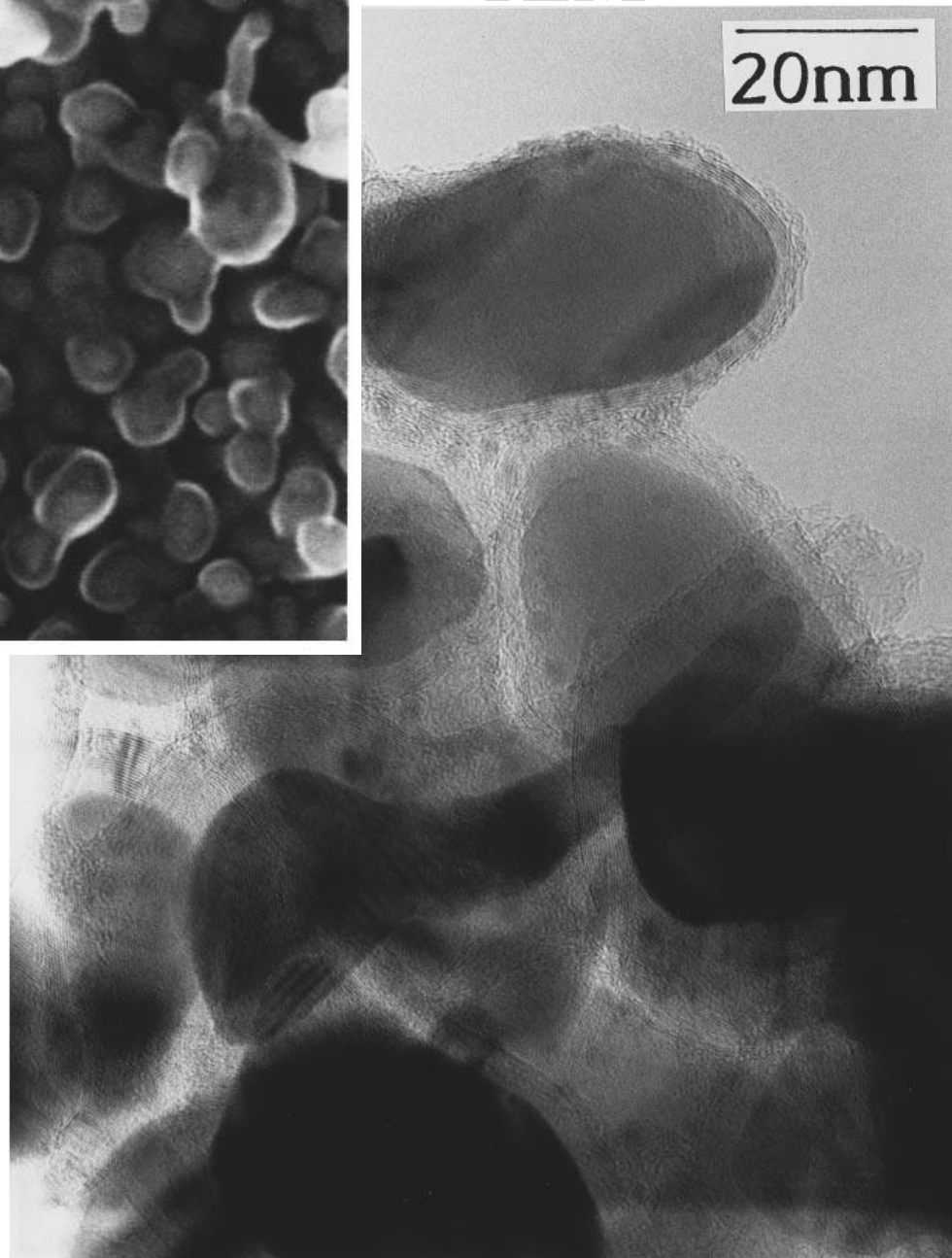
SEM

CVD for **30 minutes**

Yudasaka et al, APL 1997

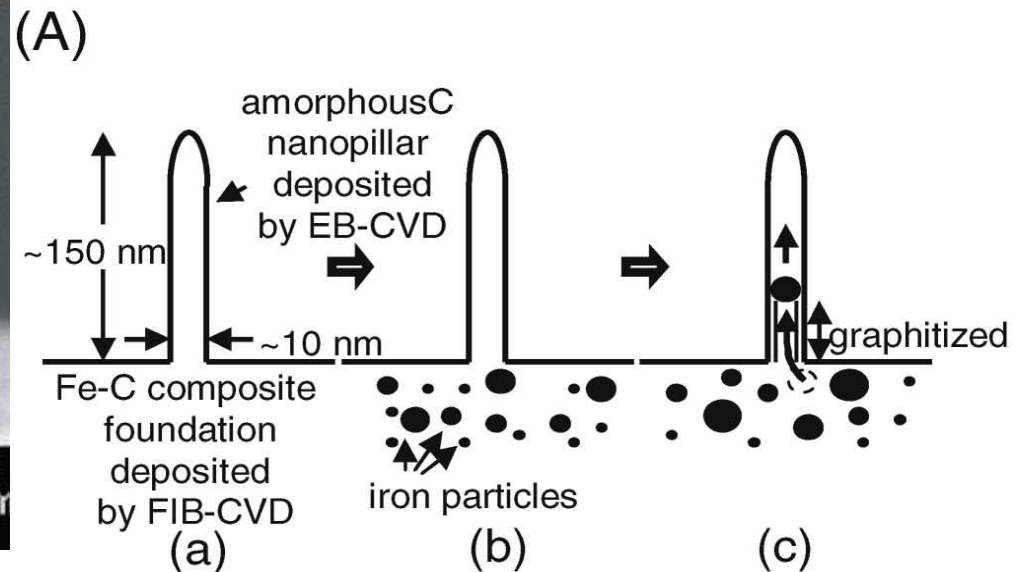
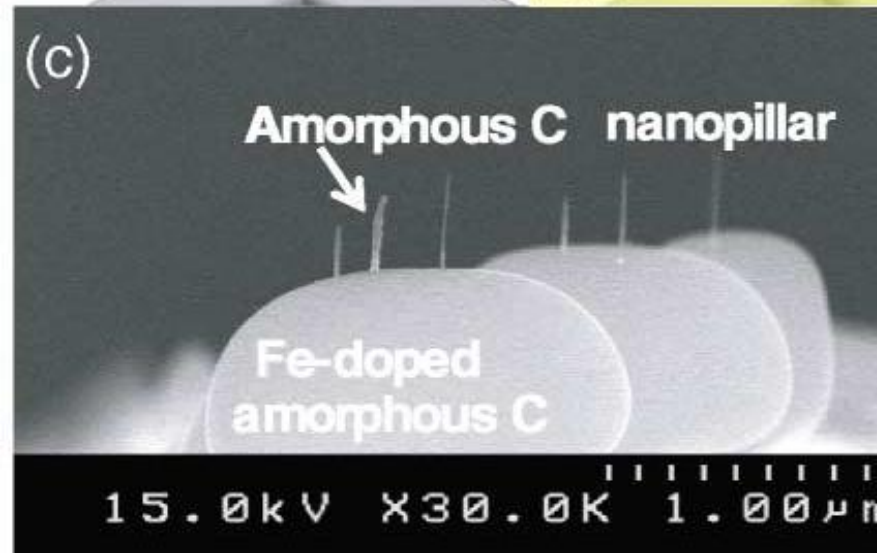
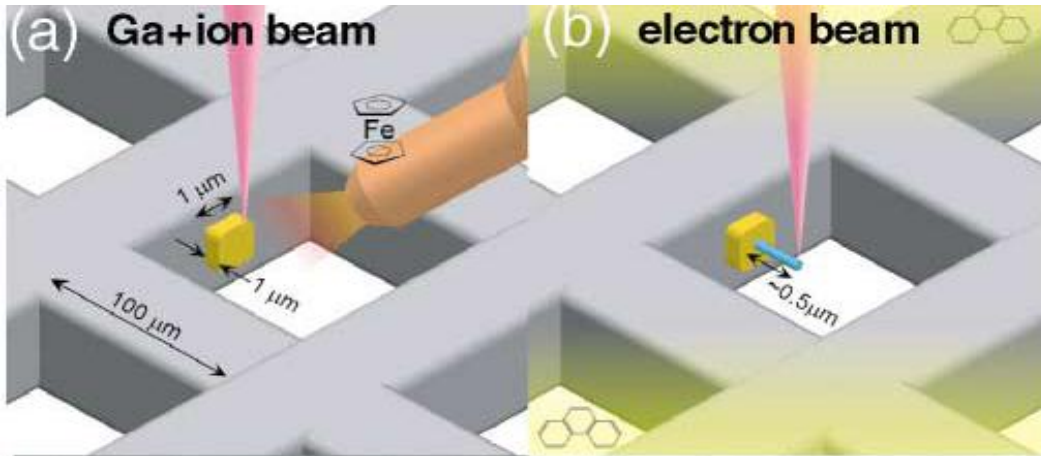
TEM

20nm



In situ Observation of Carbon-Nanopillar Tubulization Caused by Liquidlike Iron Particles

Ichihashi, Fujita, Ishida, and OchiaiPRL 92(2004)

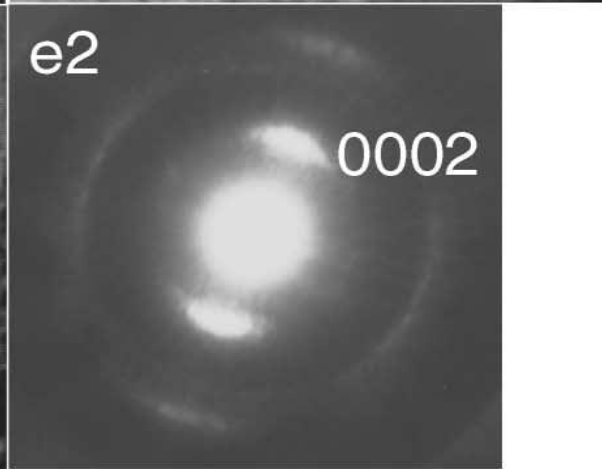
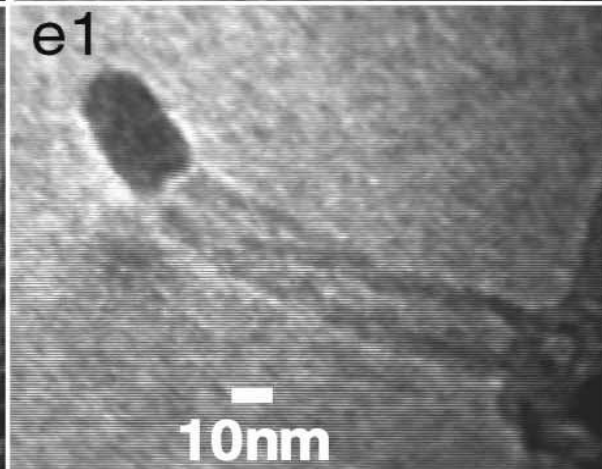
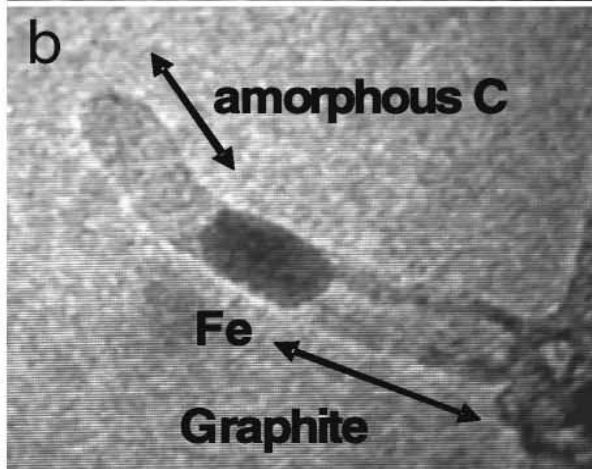
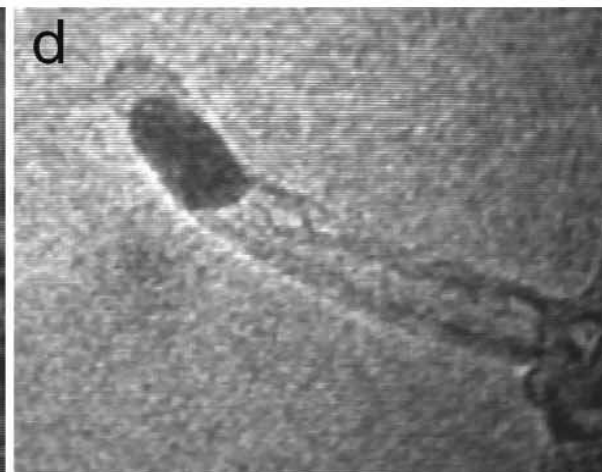
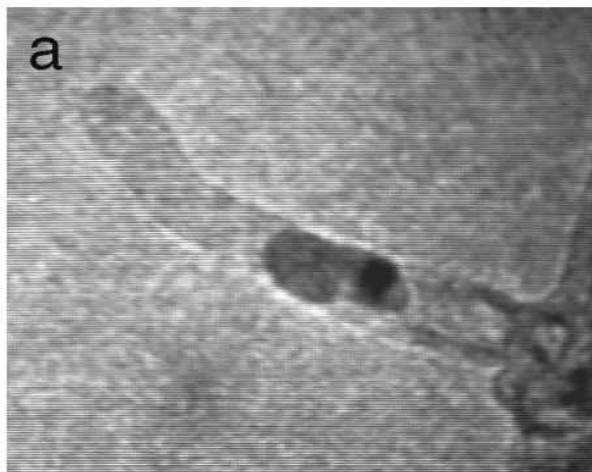


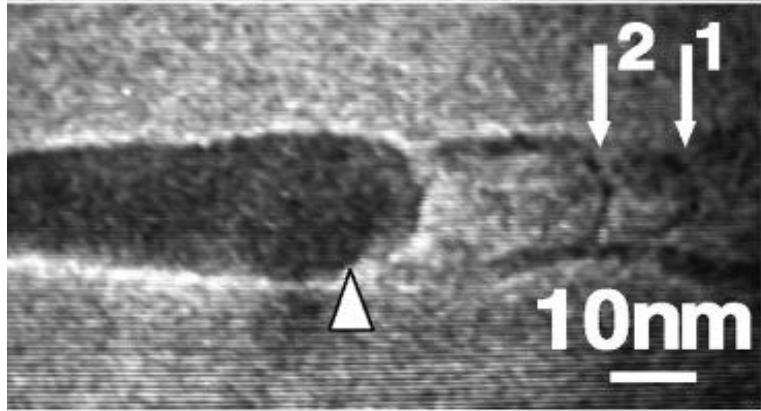
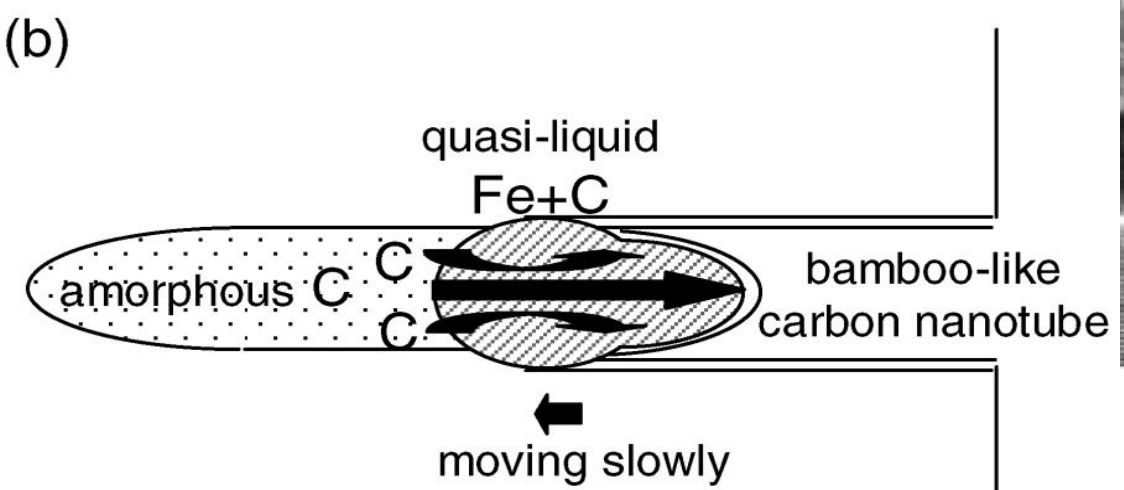
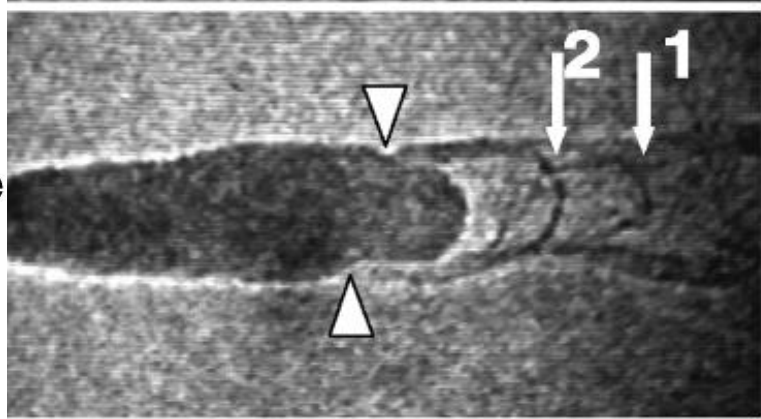
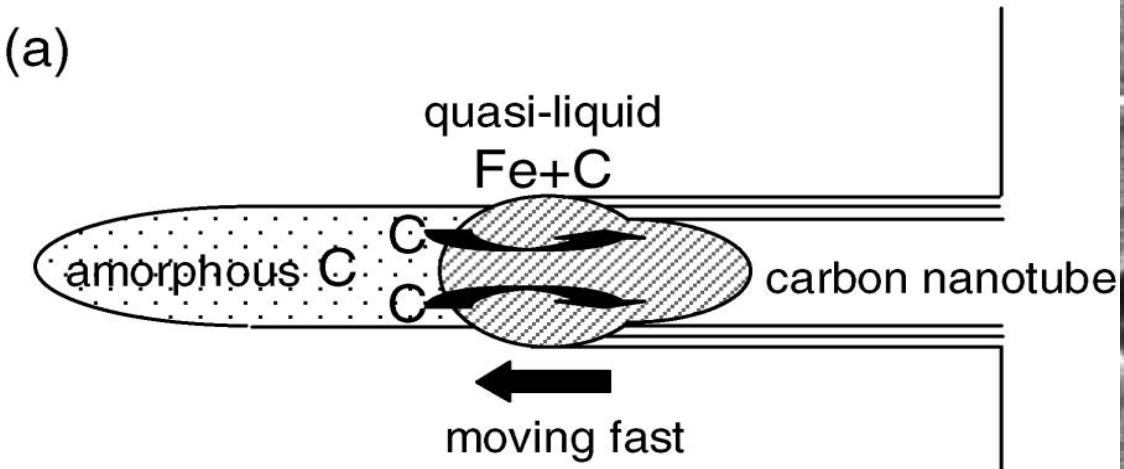
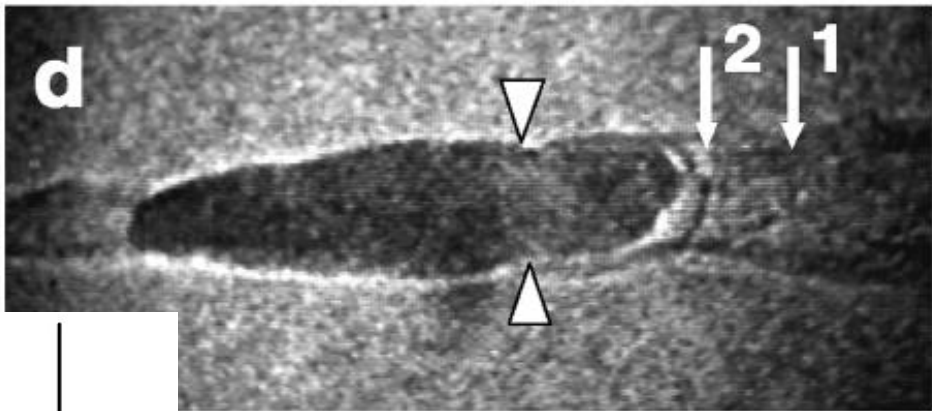
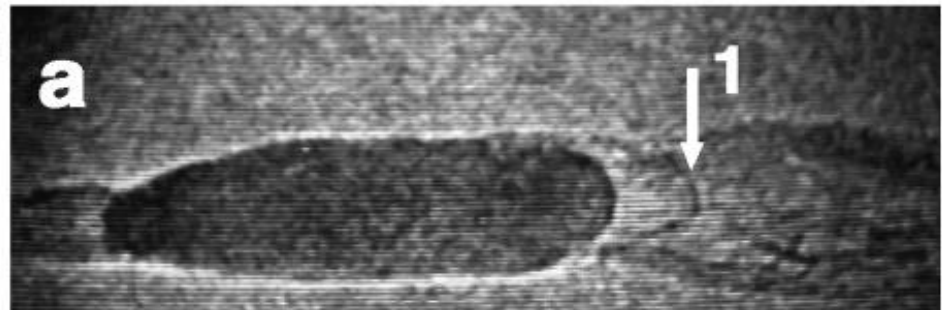
(B)

Ichihashi, et al. PRL 2004

加熱 650°C

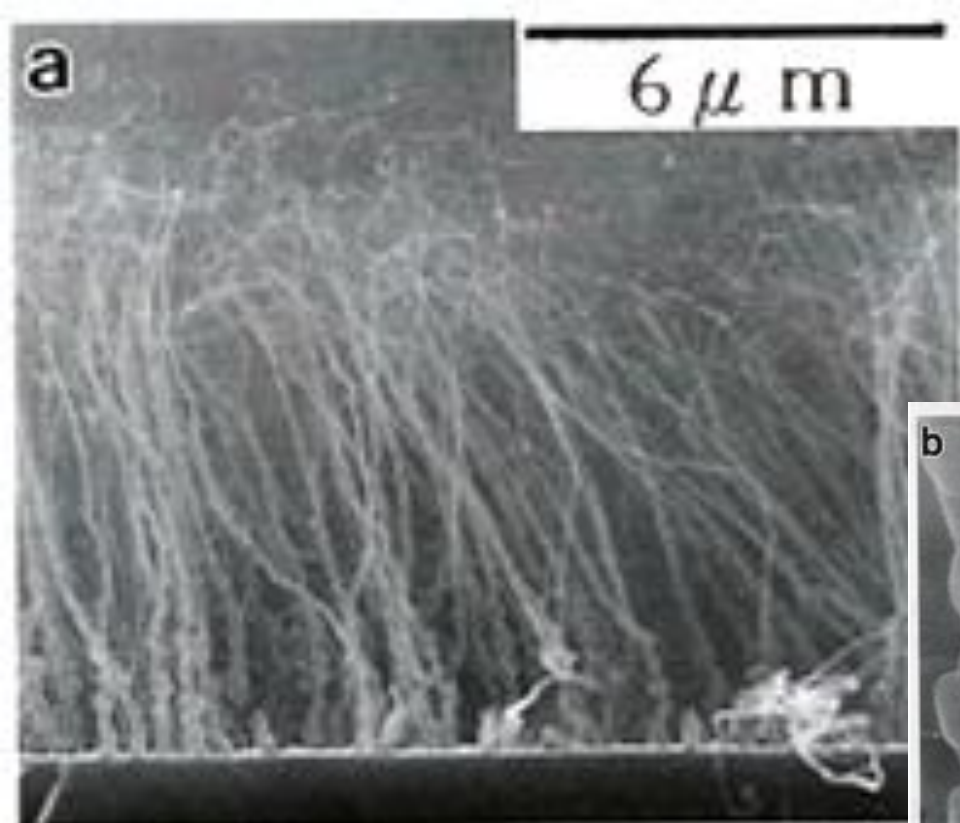
2秒ごとに撮影





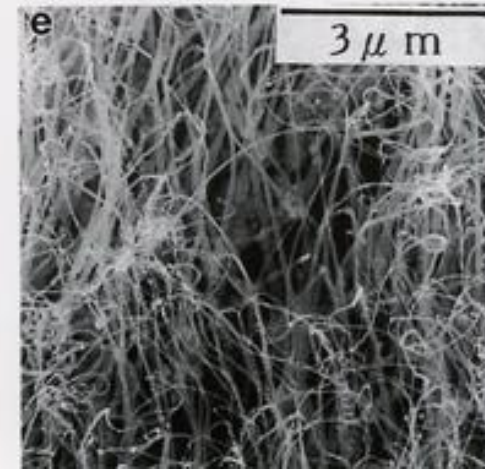
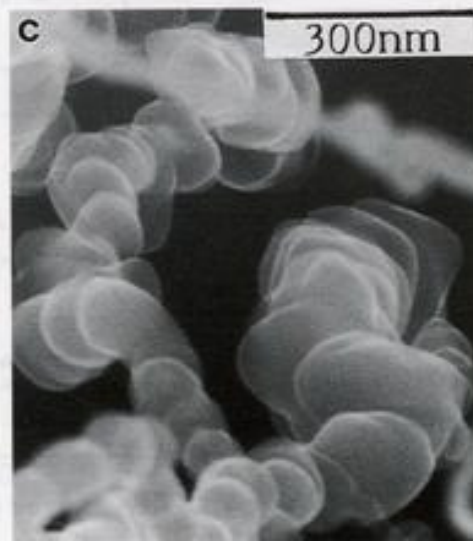
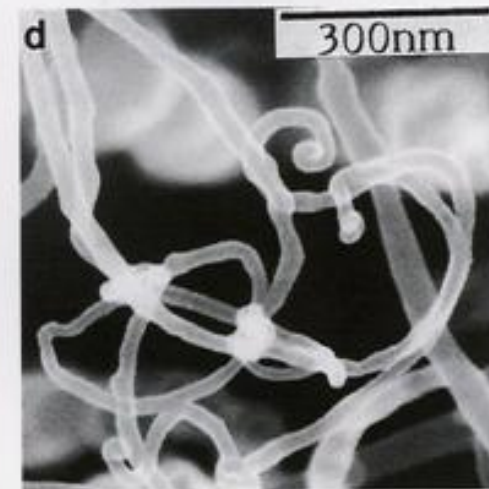
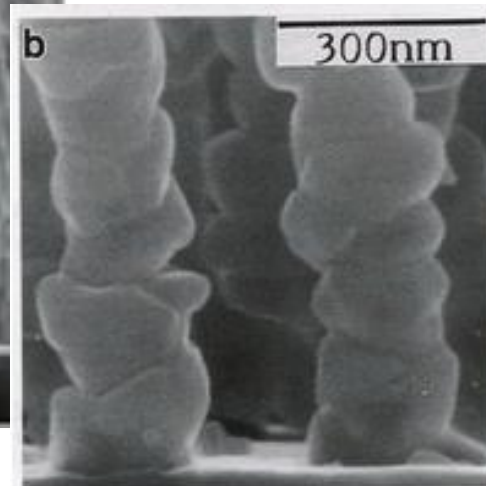
Growth model of MWNT

- Large Ni particle (50 nm <)
- Medium (20-30 nm)
- Small (<10 nm)

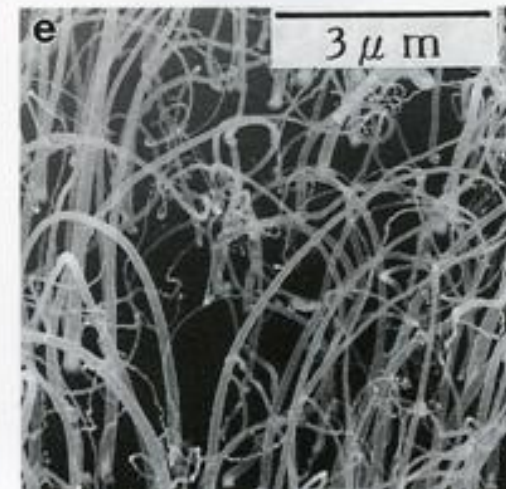
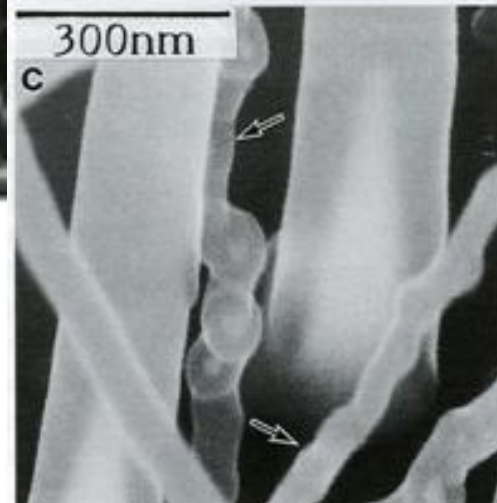
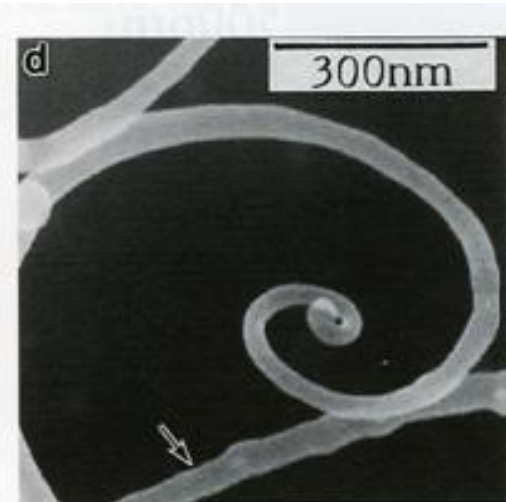
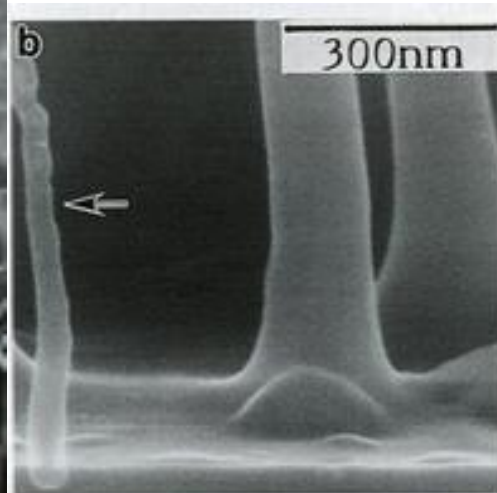
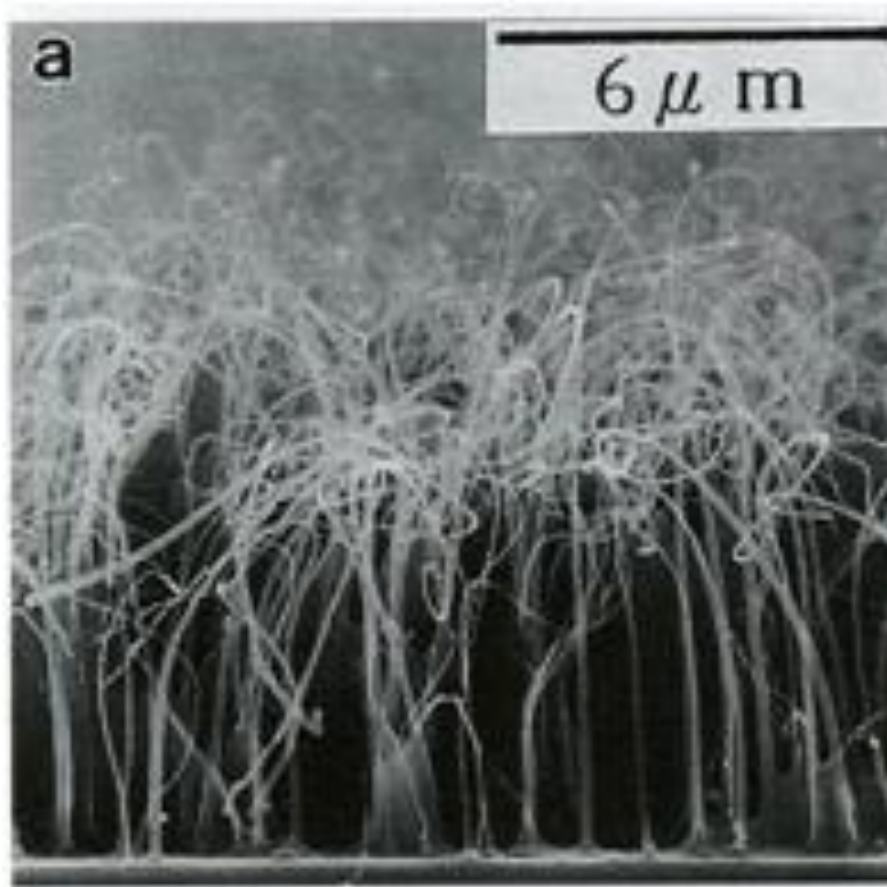


CVD 800°C

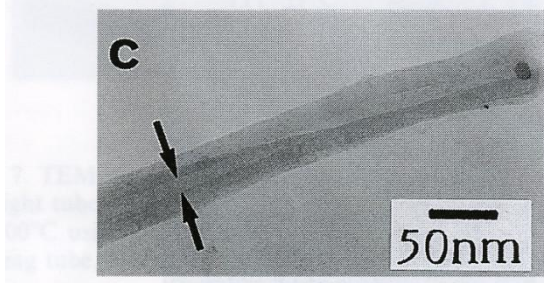
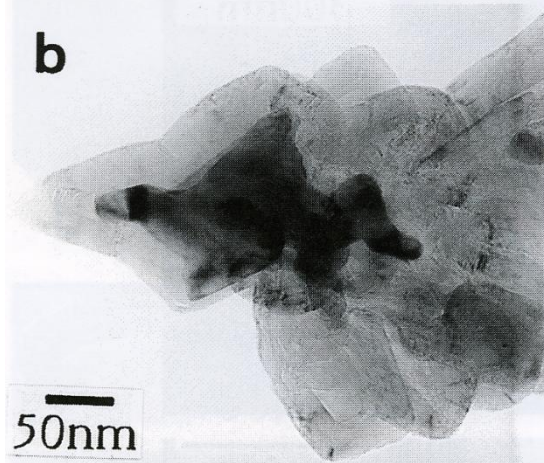
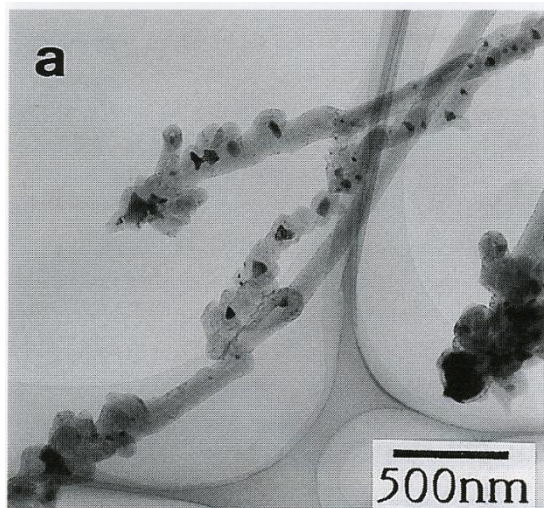
Starting material: NiPc



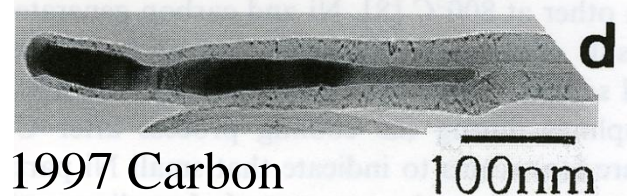
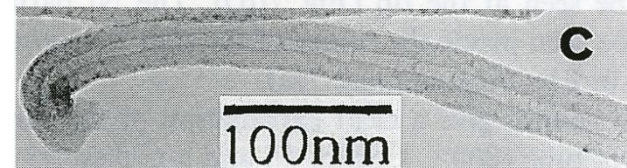
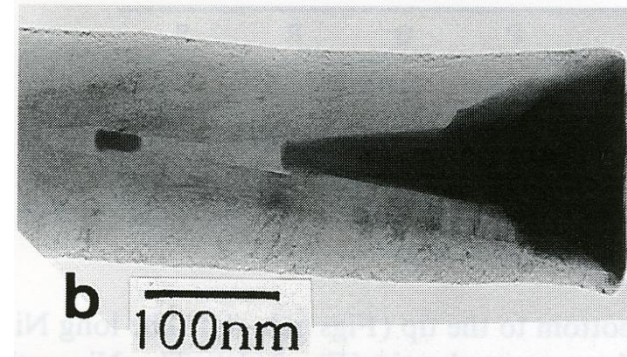
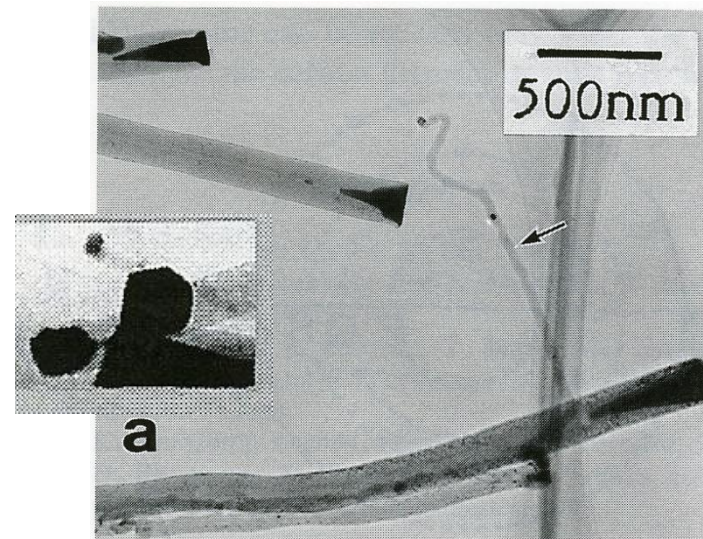
Yudasaka et al 1997 Carbon



NiPc-CVD 800°C

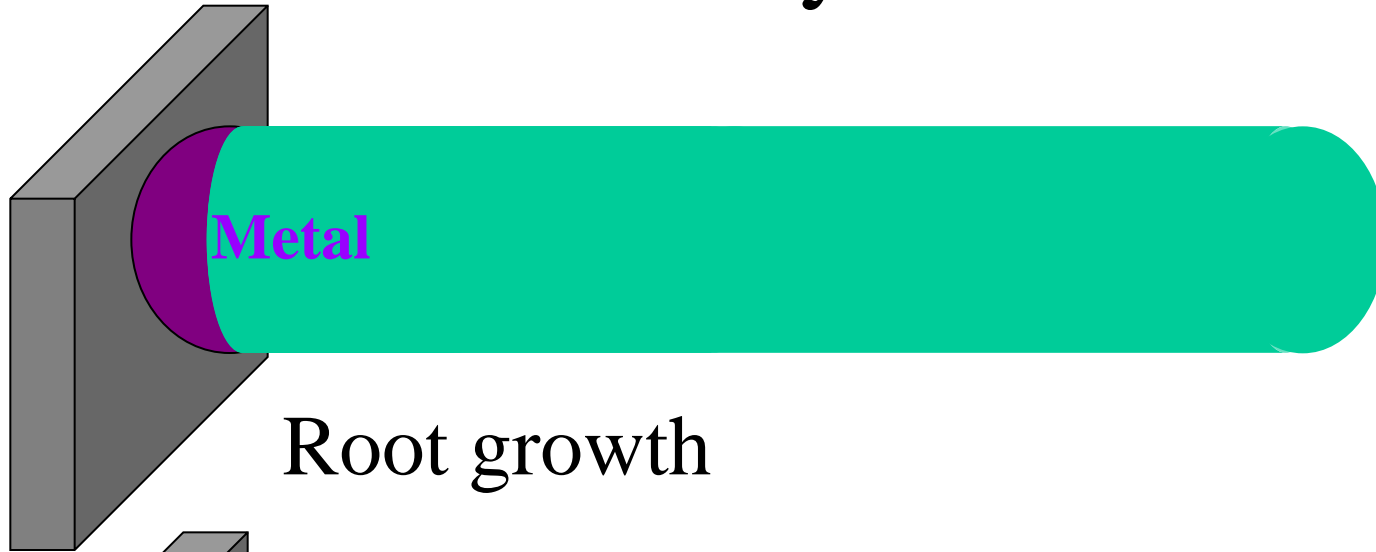


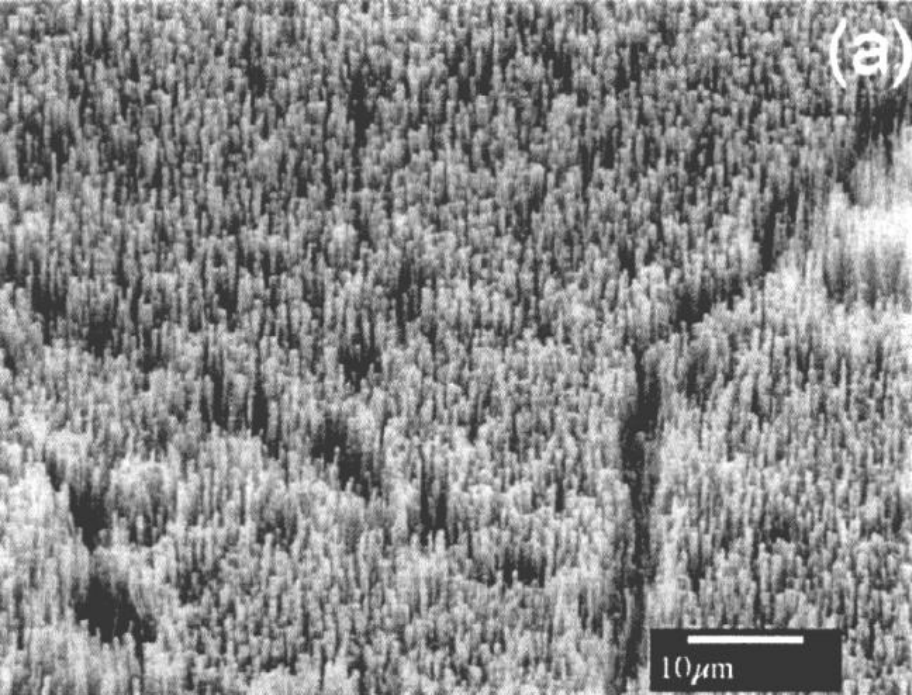
NiPc-CVD 700°C



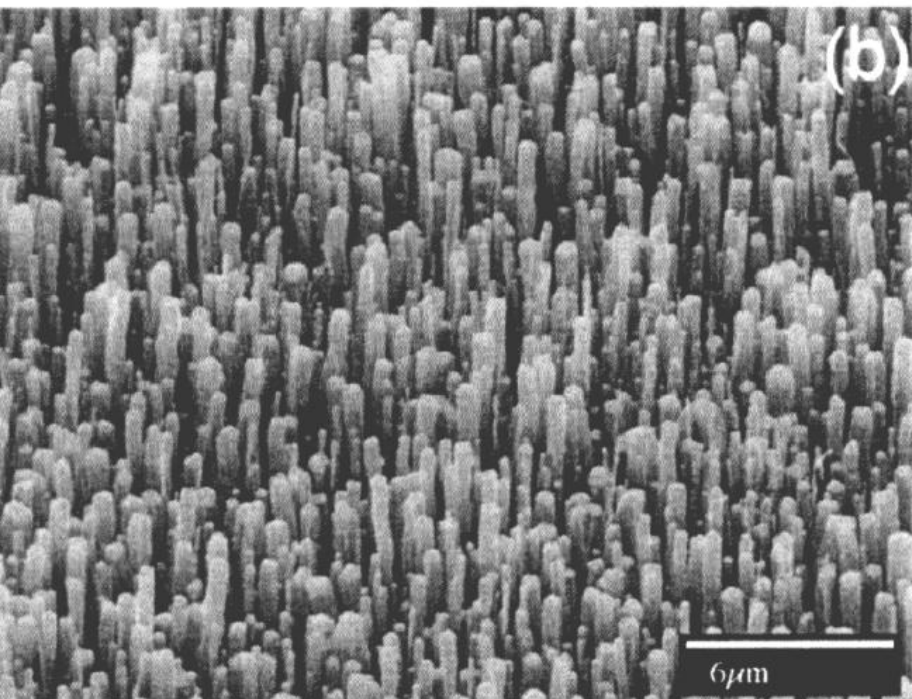
MWNT growth mechanism.

Metal catalyzed.





Plasma-enhanced hot filament CVD



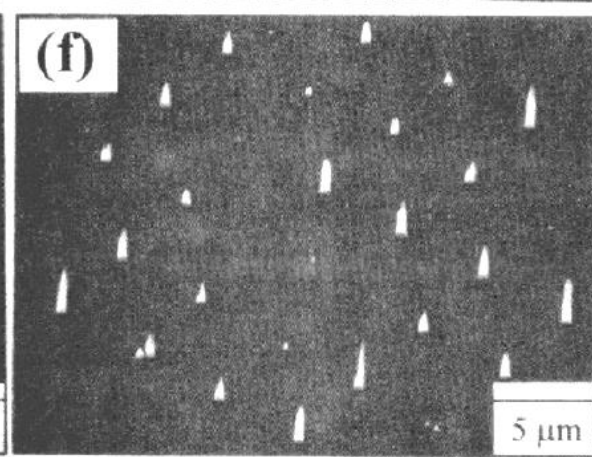
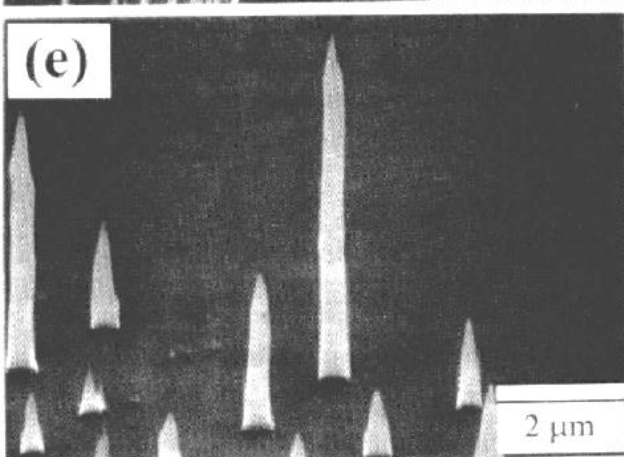
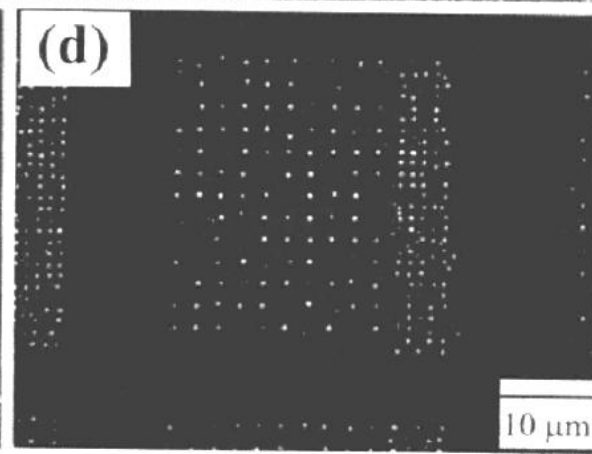
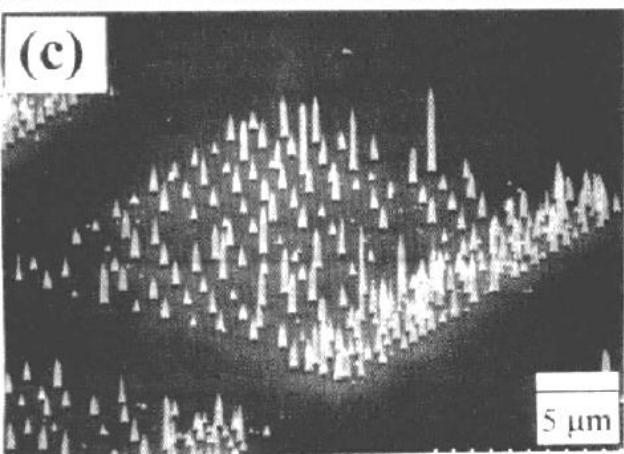
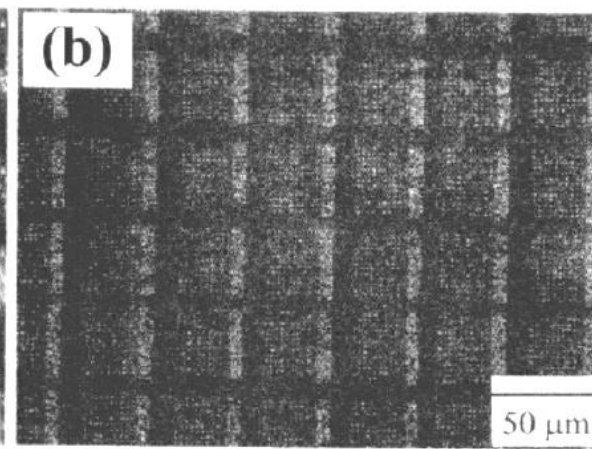
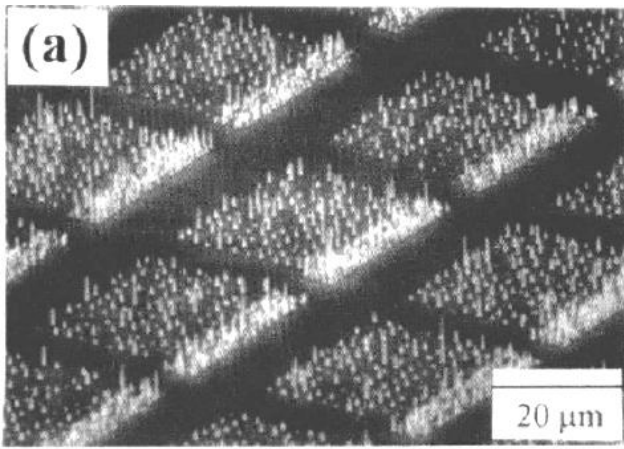
1-20 Torr acetylene, ammonia
Ni (on display glass of Corning Inc.)
Tungsten filament coil
Plasma generator
Estimated sample temperature $<666^{\circ}\text{C}$
10min – 5h

Z. P. Huang et al. Appl. Phys Lett.
73(1998)3845.

Site selective growth of MWNTs

Z. F. Ren

Appl. Phys. Lett. 75, 1086(1999)



Metal-free synthesis of MWNT

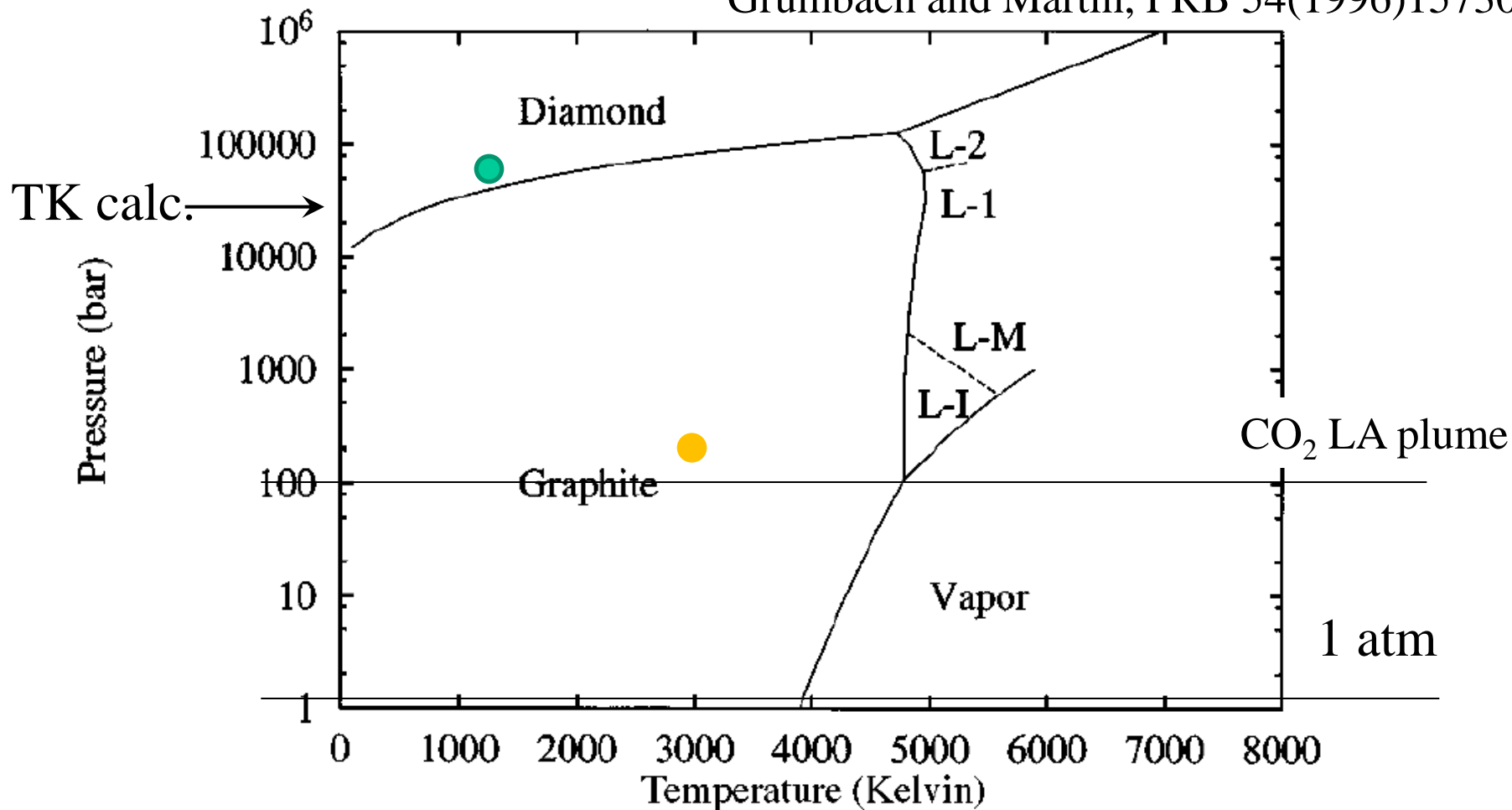
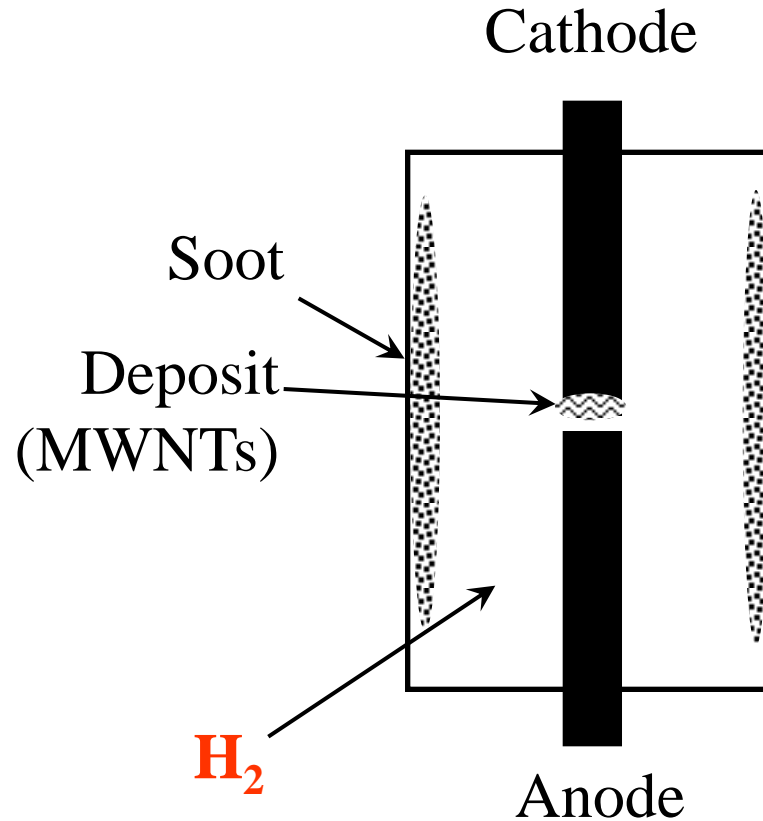


FIG. 1. Phase diagram of carbon at low pressures. Solid lines indicate phase boundaries for which some experimental evidence exists (Ref. 14). Dashed lines indicate theoretically proposed phase boundaries: liquid insulator (*L-I*) to liquid metal (*L-M*) (Ref. 15) and graphitelike liquid (*L-1*) to diamondlike liquid (*L-2*) (Ref. 16).

Arc discharge with graphite rods in H₂ atmosphere.

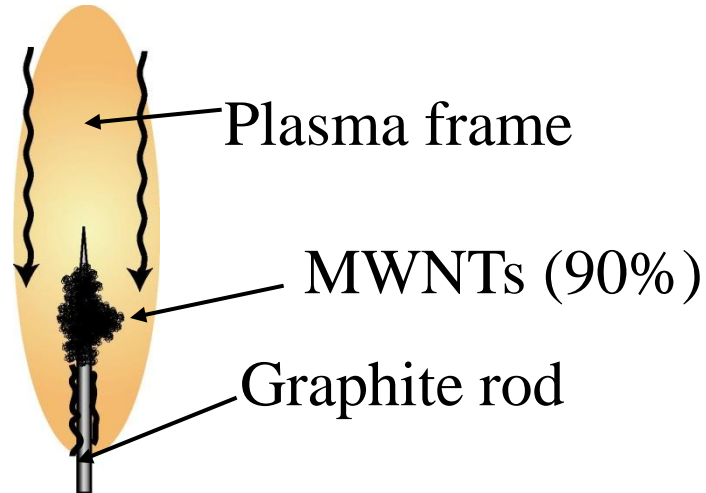


Anode evaporation rate:	10 mg/s
Yield (a-C soot or cathode deposits):	50%
Purity of MWNTs at cathode:	Low

Evaporation of graphite with HF plasma torch in Ar/H₂ atmosphere

Ar(50 L/min)

H₂(20L/min)



- No electric fields
- Ions

Koshio, Yudasaka, Iijima, *Chem. Phys. Lett.* **356**(2002)595.

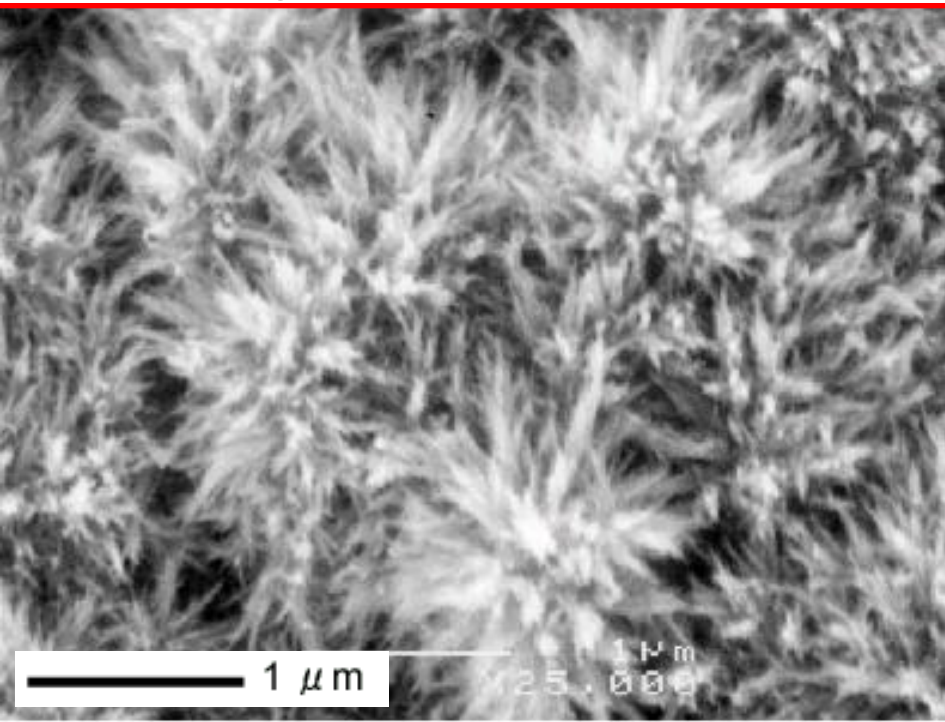
Evaporation rates of graphite, yields, and purity.
HF plasma method produces high-quality MWNTs.

Methods	Anode evaporation	Yields	Purity
Arc discharge	10 mg/s	< 30% (cathode deposit)	Low
HF plasma	0.005 mg/s	~100%	95%

Ultimate MWNTs

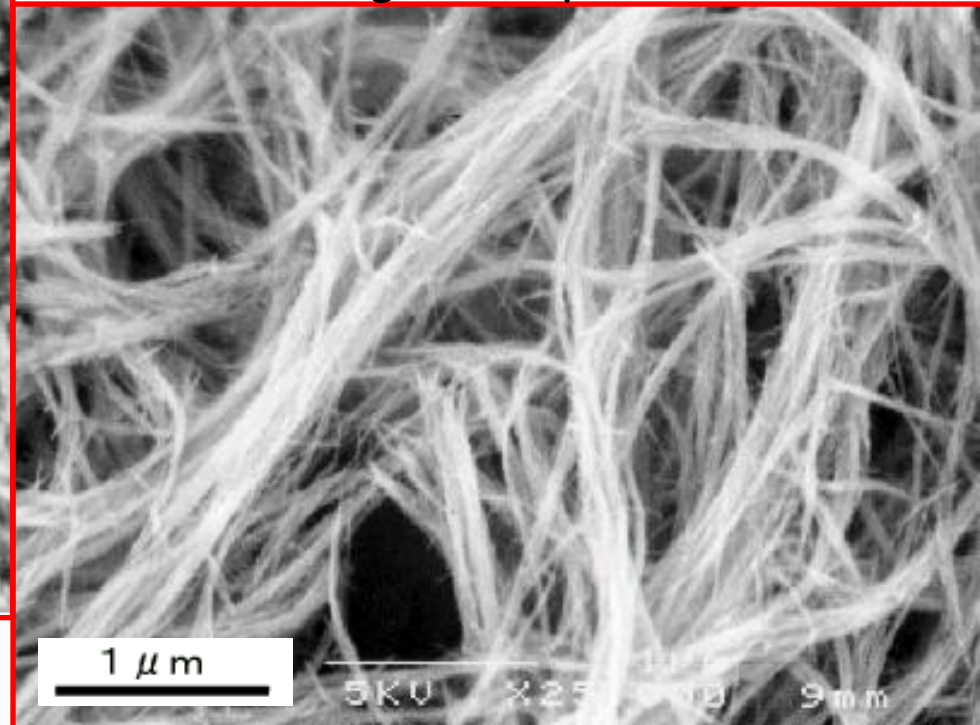
A. Koshio, M. Yudasaka, S. Iijima
Chem. Phys. Lett. **356**(2002)595.

$\varphi(\text{in})$: 0.4 nm, $\varphi(\text{out})$: 4 nm
length : micrometer order

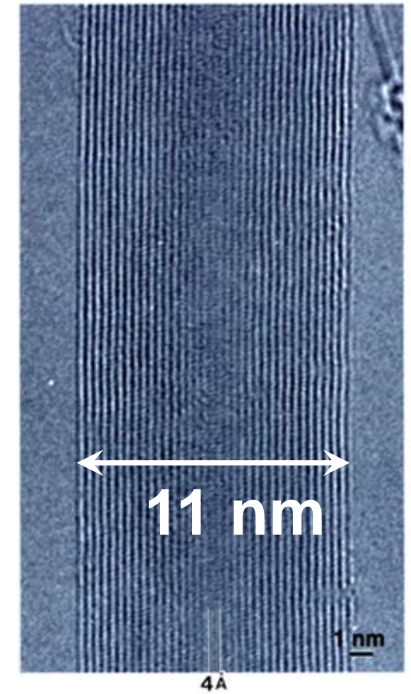
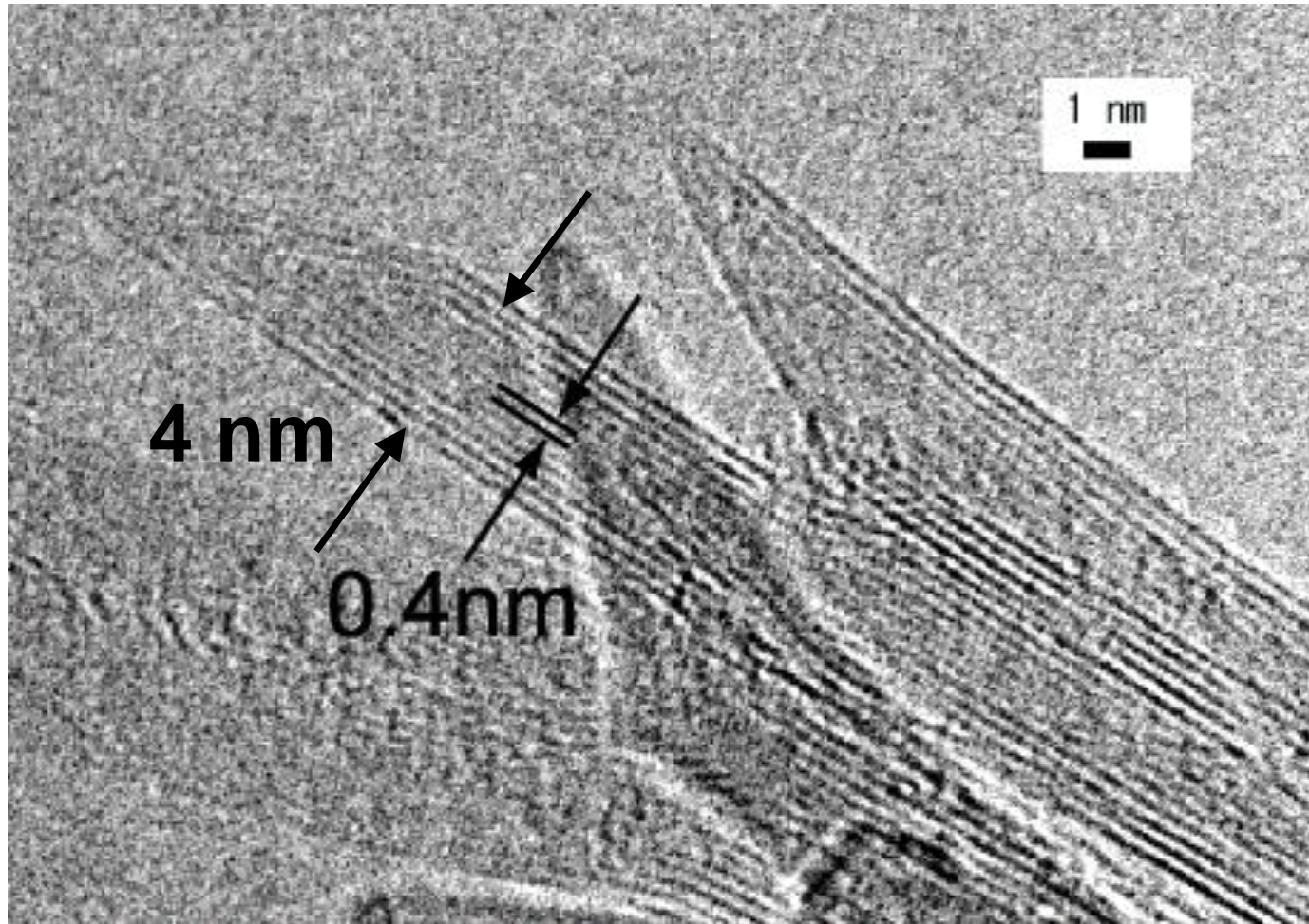


- Fully-Packed
- Highly graphitized
- Outside-diameter selective
- 95%-Purity
- Large scale production

$\varphi(\text{in})$: 0.4 nm, $\varphi(\text{out})$: 20 nm
length : ~10 μm

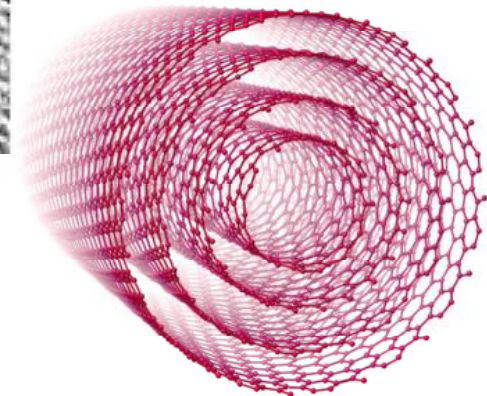


Concentric MWNTs with small outside-diameters

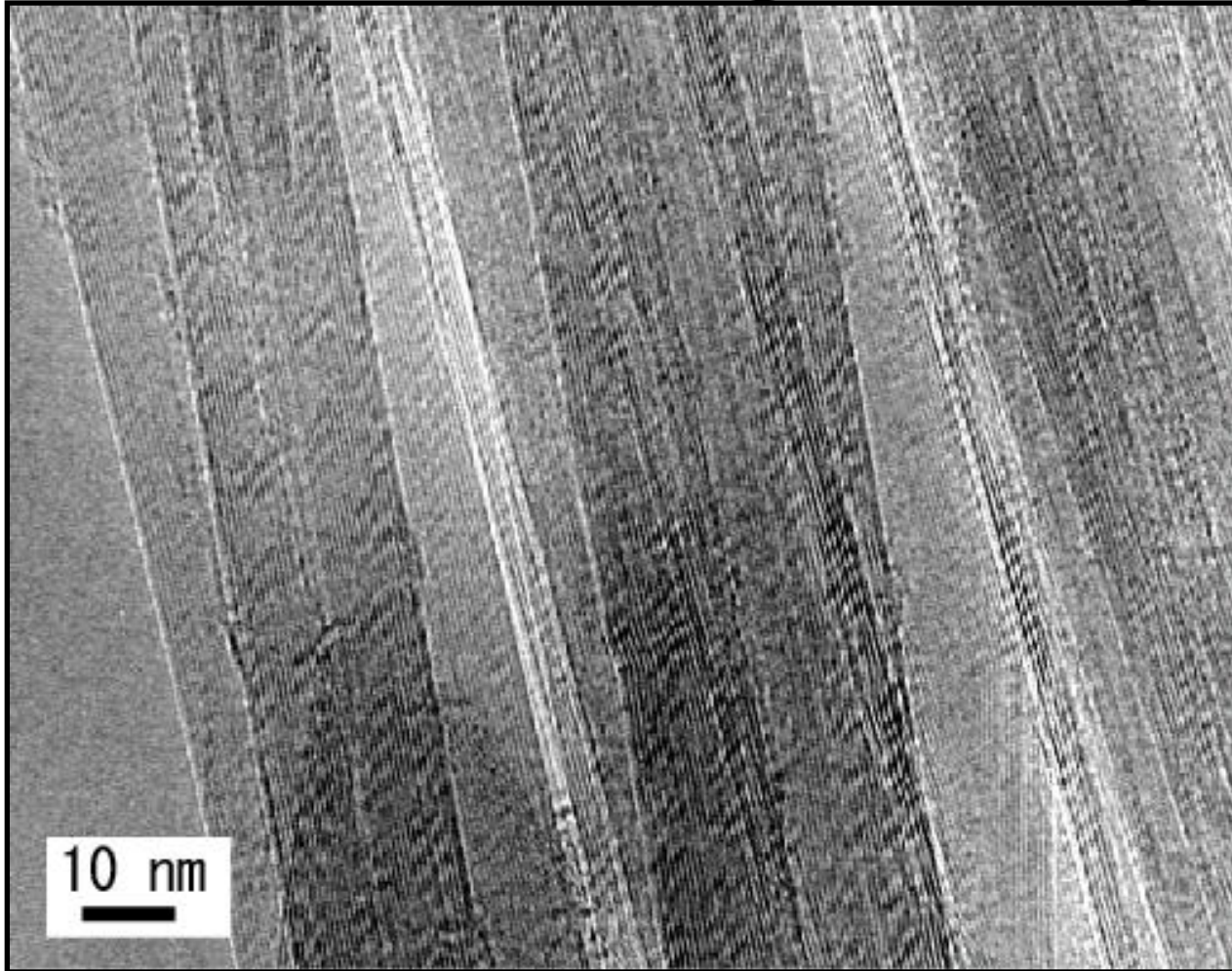


Qin et al. *Nature*
408(2000)408.

A. Koshio, M. Yudasaka, S. Iijima
Chem. Phys. Lett. **356**(2002)595.



A TEM image of long bundles



**Diameters: ~20 nm
(~30 layers)**

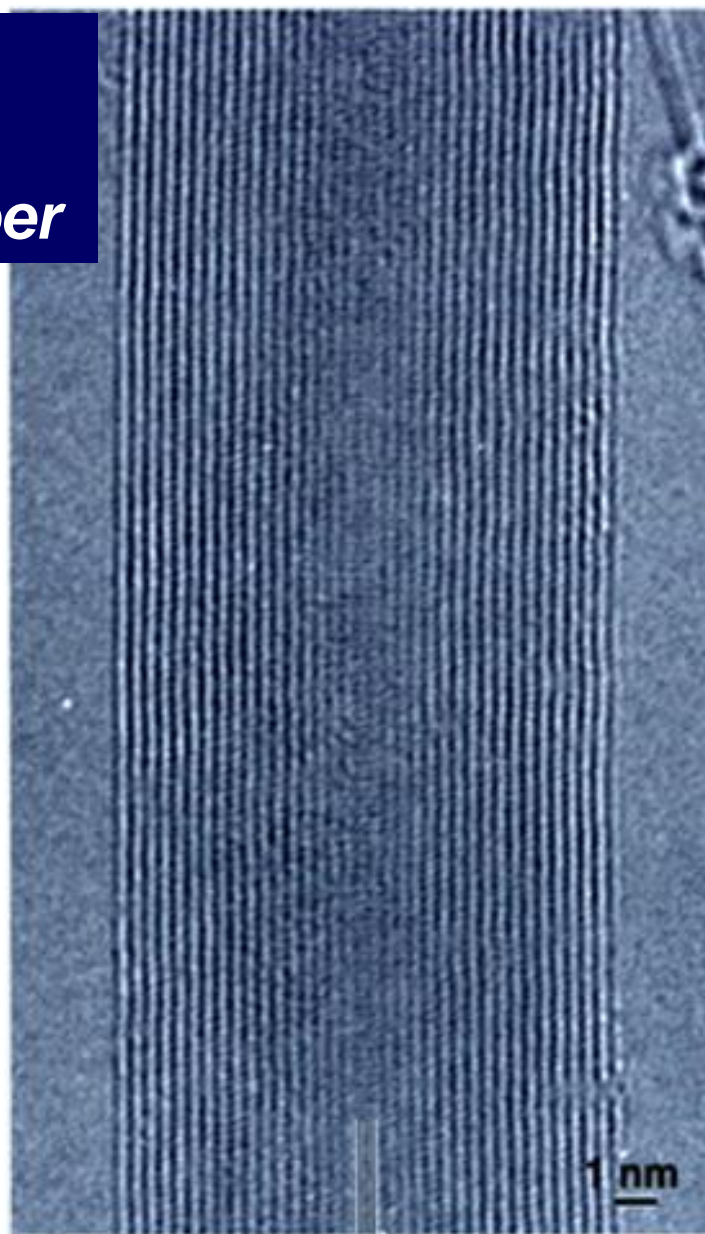
最高密度のMWNT: Densist MWNT or Densist Nanografiber

A little formed by
arc-discharge in H₂.



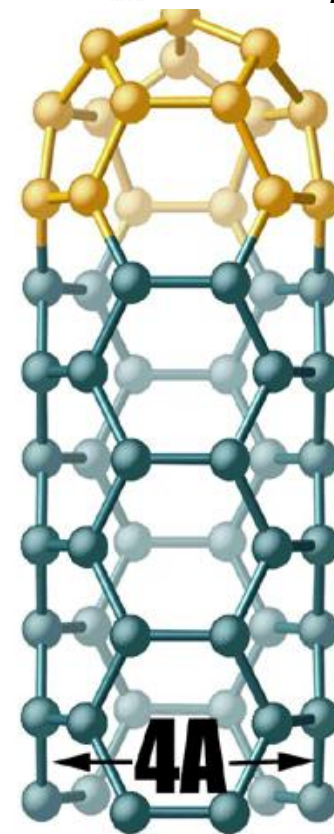
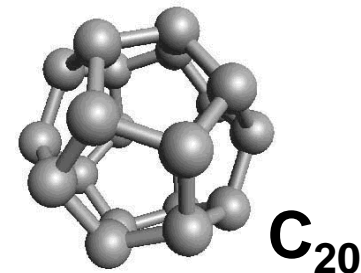
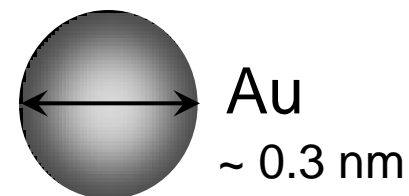
Purity of about 95%
available by HF plasma.

Koshio, Yudasaka, Iijima
Fullerene Symposium 2001



4A

1 nm



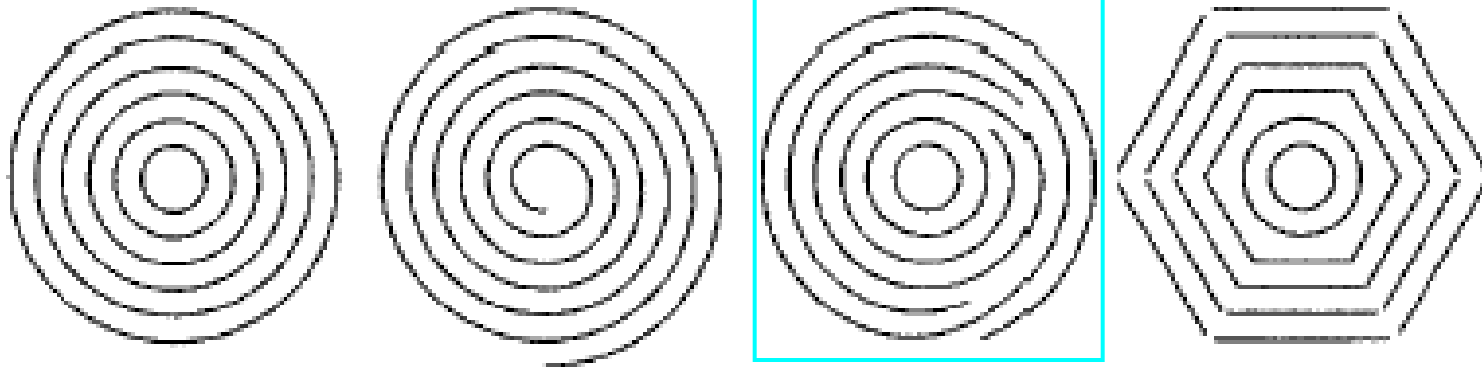
Qin, et al.

Nature 408, 50 (2000).

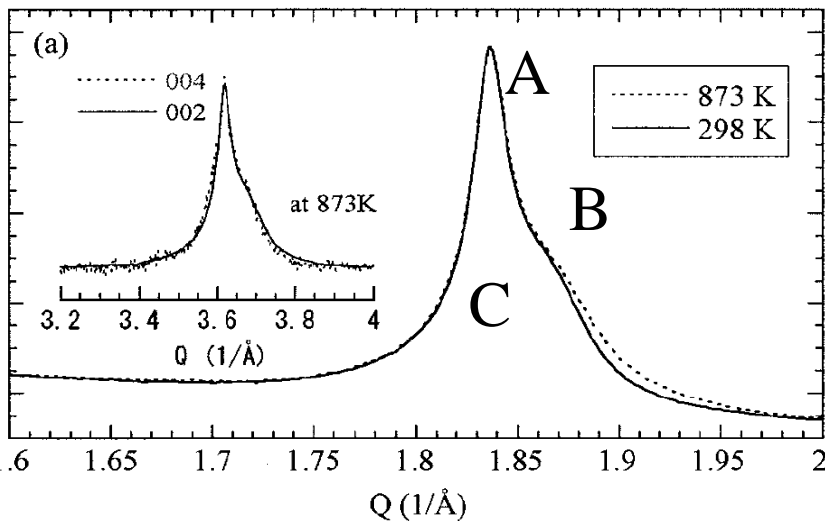
An XRD study on MWNTs (Arc discharge, H₂, No metal)

Thin MWNTs: “Concentric (Russian doll)” type

Thick MWNTs: “Scroll” and/or “Concentric”, “Polygonal”



(Amelinckx et al.)



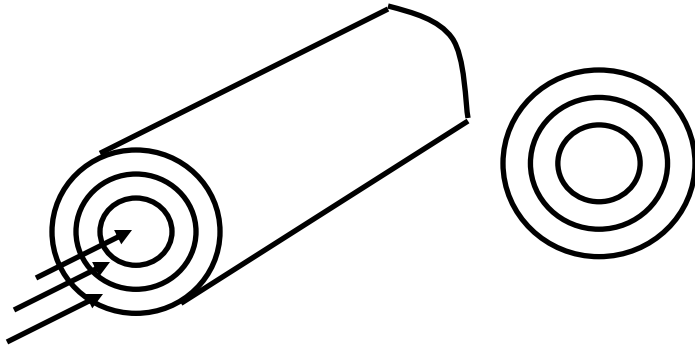
Thermal-expansion coefficients

A: $2.6 \times 10^{-5} K^{-1}$ (graphitic impurity)

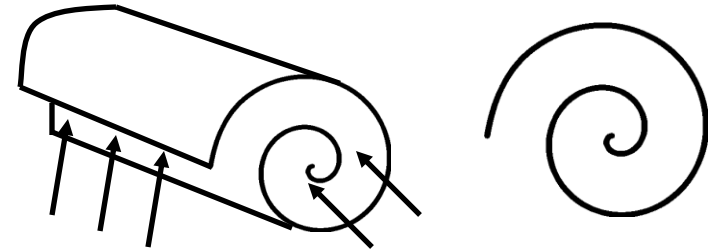
B: $2.5 \times 10^{-5} K^{-1}$ (jelly roll parts)

C: $1.6 \times 10^{-5} K^{-1}$ (concentric parts)

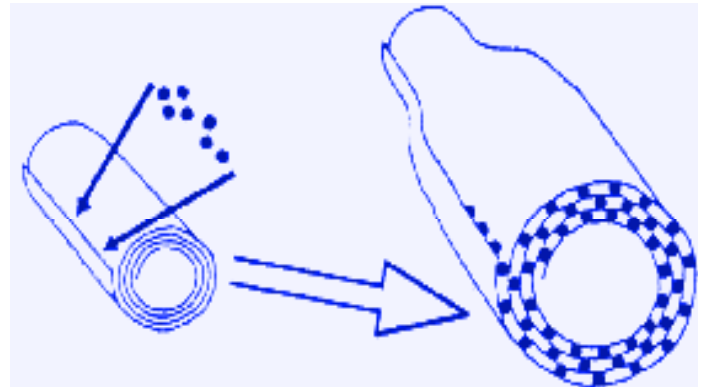
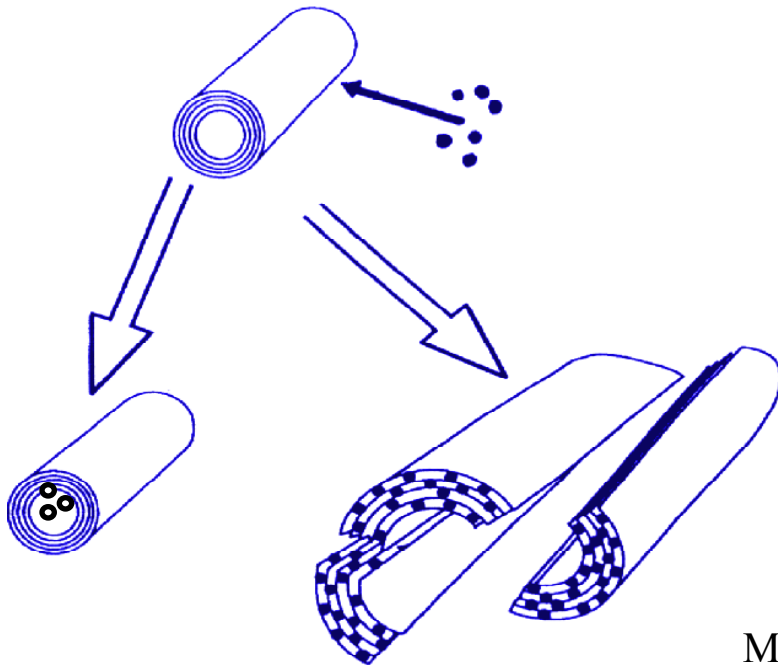
Structures of Multi-Wall Carbon Nanotubes



Russian-doll type
(CCVD)

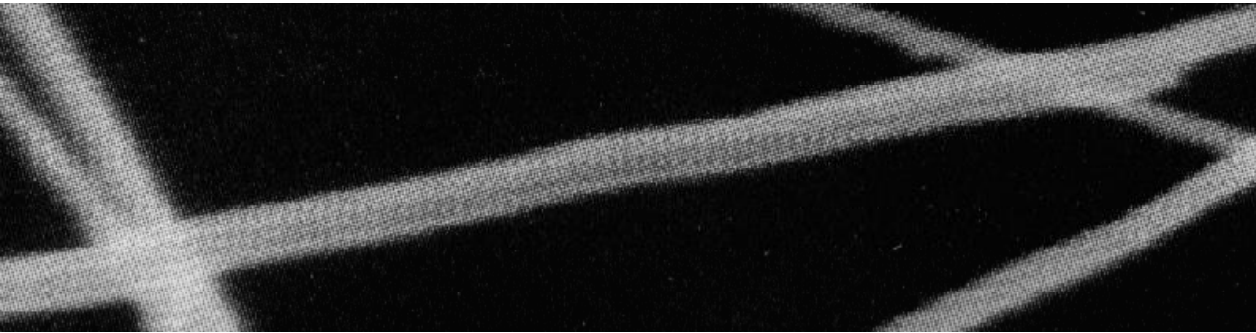


Scroll type
(Arc discharge without
metal catalysts ?)



Intercalation is possible for scroll-type MWNTs

Mordkovich et al. "Supercarbon" (Eds. Yoshimura, Chang)
Springer, 1998, p.107.



300 nm

Intercalation of
 FeCl_3 into
scroll-type MWNTs

Left in air for
1 week and
washed with
water.

